
PART NUMBER**9094FMB-ROCV**

Rochester Electronics**Manufactured Components**

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

A FAIRCHILD COMPATIBLE CURRENT SINKING LOGIC PRODUCT

MILITARY TEMPERATURE RANGE: -55°C to $+125^{\circ}\text{C}$

GENERAL DESCRIPTION

The Fairchild 9930 series of Diode Transistor Micrologic is a member of the Compatible Current Sinking Logic (CCSL) family designed for use in systems where good noise immunity, medium speed, medium power, and good fan-out are required. DT μ L is available in CERPAK and hermetically sealed Dual In-Line packages over the full military temperature range. Basic members of the family are active low level output AND gates commonly called NAND gates.

Noise immunity is typically 1 volt. Worst case noise immunity over the military temperature range is 400 mV. Power dissipation is typically 8.5 mW per gate function at a 50% duty cycle. The average propagation delay is 30 ns per gate function. A single 5 volt $\pm 10\%$ supply is used.

A variety of gate combinations is available which provides the system designer the utmost in logic flexibility and helps to reduce package requirements to a minimum. Gate outputs may be tied together to perform the wired-OR function. Some gates are provided with 2K pull-up resistors which offer improved propagation delay times. An extender is provided to increase the fan-in for some of the gates.

The 9932 buffer has active pull-up to provide increased capacitive drive and higher fan-out. The 9944 has a bare collector output to allow for wired-OR or driving of low-power lamps. Fan-in for the buffers can be extended with the use of the 9933.

The binary products are direct coupled master-slave flip-flops making operation independent of the clock pulse rise and fall times. The binary products incorporate direct clear, direct set, and buffered outputs to provide output isolation from the slave circuitry.

The V_{CC} and ground terminals of all devices are located on diagonal corners of the package which allow two degrees of freedom in routing of power and ground lines on the P/C boards. Simple loading rules are incorporated so that the fan-in and fan-out capability of each device can be quickly established.

The DT μ L 9930 series is compatible with the CCSL devices which include LPDT μ L, TT μ L, M μ L, Medium Scale Integration (MSI), and Micromatrix™ array products.

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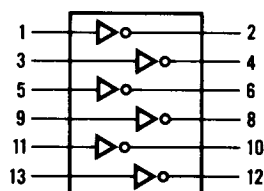
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FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

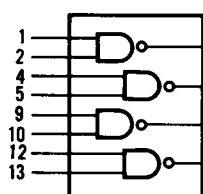
9300 SERIES DT_μL INTEGRATED CIRCUITS

HEX INVERTERS

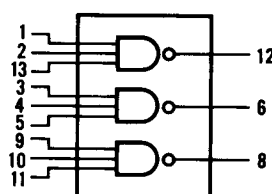


9936, 9937

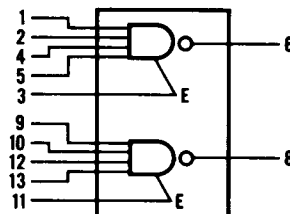
NAND GATES



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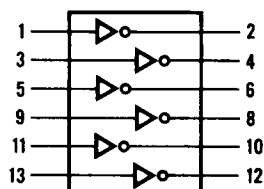


9962, 9963



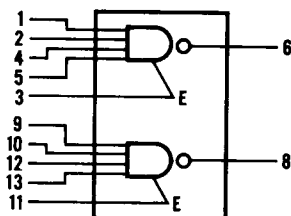
9930, 9961

EXTENDABLE HEX INVERTER



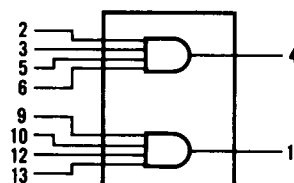
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BUFFERS



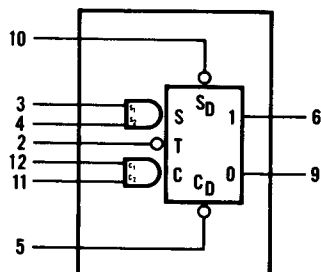
9932, 9944

EXTENDER

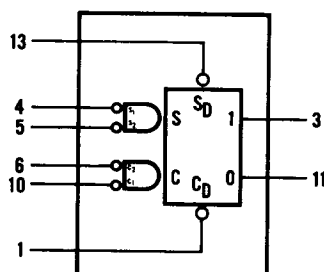


9933

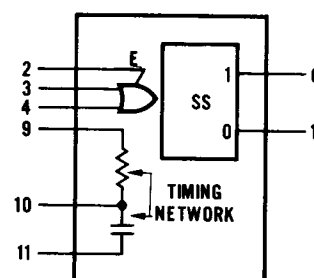
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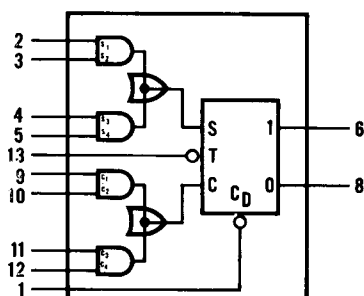
9945, 9948



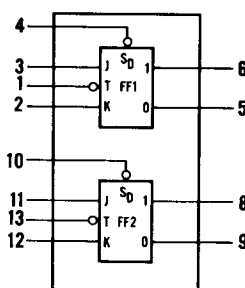
9950



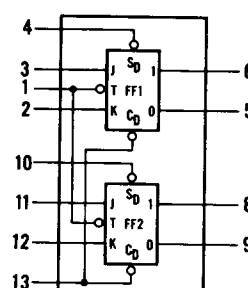
9941, 9951



9111



9093, 9094



9097, 9099

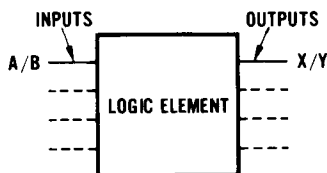
V_{CC} = 14
GND = 7

ABSOLUTE MAXIMUM RATINGS (Above which useful life may be impaired)

Storage Temperature	-65°C to 150°C
Temperature (Ambient) under bias	-55°C to 125°C
V _{CC} pin potential to ground	-0.5 V to +8.0 V
V _{CC} , pulsed 1 second	12 V
Input voltage, applied to input	-1.5 V to 5.5 V
Voltage applied to output when output is high	+V _{CC}
Input current, into inputs	1.0 mA
Current into output when output is low (except 9932 & 9944)	30 mA
Current into output when output is low (9932 & 9944)	100 mA
Lead temperature (soldering, 60 seconds)	300°C

LOADING RULES

In this data sheet the following notation has been chosen to indicate the input loading and output drive for all logic elements.



Where

- A = high logic level input load factor
- B = low logic level input load factor
- X = high logic level output drive factor
- Y = low logic level output drive factor

When checking for loading violations it is only necessary to insure that the sum of the high logic level input load factors at any node does not exceed the high logic level output drive factor at that node. The same is true for low logic level load and drive factors. These rules apply only within the DTμL 9930 series. For loading rules to other Fairchild logic elements refer to the CCSL Composite Data Sheet.

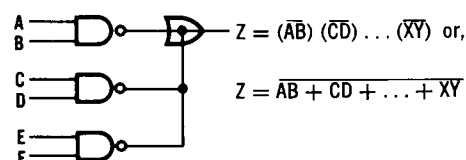
Multiplying the factor with the appropriate current per unit load gives the input loading or output drive in terms of current. For the DTμL circuits of this data sheet, current per unit load is -1.5 mA maximum at low logic level and is 5 μA maximum at high logic level.

In the case where unused inputs of an AND gate are shorted to a driven input, the high logic level input load factor for inputs will be the number of inputs shorted together times the high logic level input load factor for one input. The low logic level input load factor for the inputs will be the same as that for a single input.

FANOUT REDUCTION RULES FOR WIRED-OR APPLICATIONS

Each DTμL output has a pull-up resistor connected to the output (except 9932 and 9944 and 9950). In wired-OR applications, any gate must be able to sink the current from all pull-up resistors in addition to the loads connected to the common wired "AND" point.

A 6K pull-up resistor represents 0.82 unit loads (U.L.) and a 2K pull-up resistor represents 2.3 U.L. To calculate the load driving capability of a wired-OR configuration simply find the total U.L. contribution of excess pull-up resistors. The FAN-OUT of the wired AND is then the fan-out of the lowest rated fan-out gate in the wired-OR combination minus the excess pull-up resistor contribution.



NAND GATES—9930, 9946, 9949, 9961, 9962, 9963 HEX INVERTERS—9936, 9937

DESCRIPTION

The 9930, 9946 and 9962 are active low NAND gates. The 9936 is a hex inverter with input and output characteristics identical to the NAND gates. The variety of gate combinations provides the system designer the utmost in logic flexibility and reduces package count.

The 9961, 9949, 9937 and 9963 are versions of the 9930, 9946, 9936 and 9962 with 2K collector pullup resistors in place of 6K pullup resistors. These gates have increased speeds and greater high level drive factors over their 6K counterparts.

Fig. 1—LOGIC SYMBOL AND PIN CONFIGURATIONS

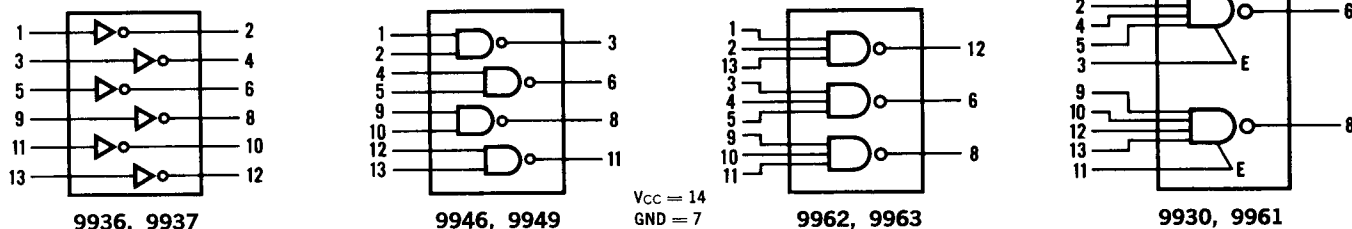
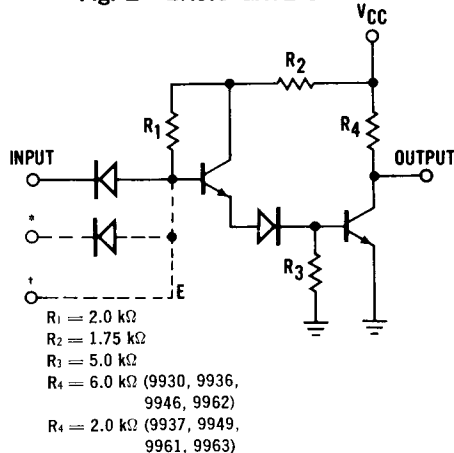


Fig. 2—BASIC GATE CIRCUIT



* Number of inputs depends on the gate.

† 9930 and 9961 only.

Fig. 3—LOADING FACTORS
(9930, 9936, 9946, 9962)

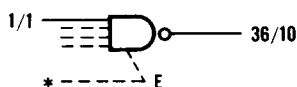
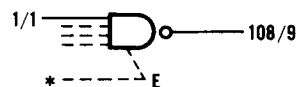


Fig. 4—LOADING FACTORS
(9937, 9949, 9961, 9963)



*Extender pin on 9930, 9963 allows increased number of inputs by addition of discrete diodes or extender element DTμL9933.

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

TABLE I
ELECTRICAL CHARACTERISTICS OF 6K GATES — 9930, 9936, 9946 AND 9962 ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS						UNITS	CONDITIONS AND COMMENTS	
		-55°C		+25°C		+125°C				
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
V _{OH}	Output High Voltage	2.5		2.6	3.5		2.5		Volts	V _{CC} = 4.5 V, I _{OH} = -0.18 mA Inputs at V _{IL} (See Below)
V _{OL}	Output Low Voltage		0.4		0.25	0.4		0.4	Volts	V _{CC} = 4.5 V, I _{OL} = 12 mA V _{CC} = 5.5 V, I _{OL} = 15 mA Inputs at V _{IH} (See Below)
V _{IH}	Input High Voltage	2.1		1.9			1.7		Volts	Guaranteed Input High Threshold For All Inputs
V _{IL}	Input Low Voltage		1.4			1.1		0.8	Volts	Guaranteed Input Low Threshold For All Inputs
I _F	Input Load Current		-1.5		-1.2	-1.5		-1.4	mA	V _{CC} = 5.5 V
			-1.16		-0.93	-1.16		-1.08	mA	V _F = 0.4 V
I _R	Input Leakage Current					2.0		5.0	μA	V _{CC} = 4.5 V
										4.0 V on other inputs
										V _{CC} = 5.5 V, V _R = 4.0 V
										Ground on other inputs
I _{PD} (per gate)	V _{CC} Current "Gate On"				2.41	3.25			mA	Inputs Open
	V _{CC} Current "Gate Off"				1.15	1.47			mA	Inputs Grounded
t _{pd+}	Turn Off Delay			25	45	80			ns	V _{CC} = 5.0 V, See Page 6, Fig. 7
t _{pd-}	Turn On Delay			10	20	30			ns	

TABLE II
ELECTRICAL CHARACTERISTICS OF 2K GATES — 9937, 9949, 9961 AND 9963 ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS						UNITS	CONDITIONS	
		-55°C		+25°C		+125°C				
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
V _{OH}	Output High Voltage	2.5		2.6	3.5		2.5		Volts	V _{CC} = 4.5 V, I _{OH} = -0.54 mA Inputs at V _{IL} (See Below)
V _{OL}	Output Low Voltage		0.4		0.27	0.4		0.4	Volts	V _{CC} = 4.5 V, I _{OL} = 10.8 mA V _{CC} = 5.5 V, I _{OL} = 13.5 mA Inputs at V _{IH} (See Below)
V _{IH}	Input High Voltage	2.1		1.9			1.7		Volts	Guaranteed Input High Threshold For All Inputs
V _{IL}	Input Low Voltage		1.4			1.1		0.8	Volts	Guaranteed Input Low Threshold For All Inputs
I _F	Input Load Current		-1.5		-1.2	-1.5		-1.4	mA	V _{CC} = 5.5 V
			-1.16		-0.93	-1.16		-1.08	mA	V _F = 0.4 V
I _R	Input Leakage Current								μA	V _{CC} = 4.5 V
						2.0		5.0		4.0 V on other inputs
I _{PD} (per gate)	V _{CC} Current "Gate On"				4.05	5.45			mA	V _{CC} = 5.5 V, V _R = 4.0 V
	V _{CC} Current "Gate Off"				1.15	1.47			mA	Ground on other inputs
t _{pd+}	Turn Off Delay			10	35	50			ns	Inputs Open
t _{pd-}	Turn On Delay			10	20	30			ns	Inputs Grounded
										V _{CC} = 5.0 V, See Page 6, Fig. 7

ELECTRICAL CHARACTERISTICS

Fig. 5a
WORST CASE POWER
DISSIPATION VERSUS
AMBIENT TEMPERATURE

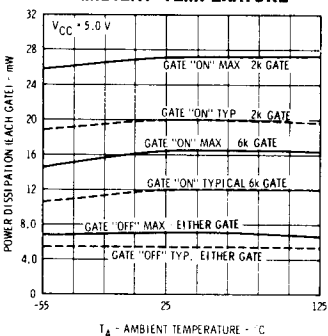


Fig. 5b
WORST CASE LOGIC LEVELS
VERSUS
AMBIENT TEMPERATURE

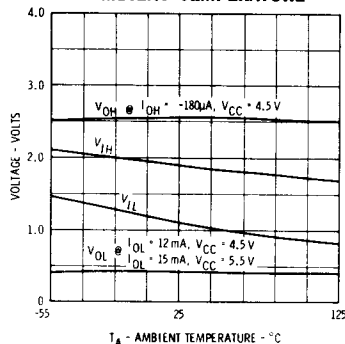


Fig. 5c
WORST CASE HIGH LEVEL
NOISE IMMUNITY VERSUS
AMBIENT TEMPERATURE

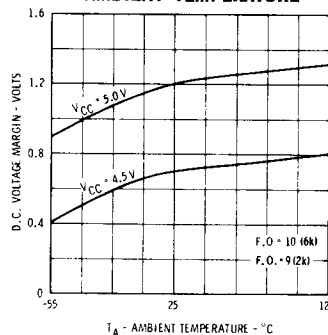


Fig. 5d
WORST CASE LOW LEVEL
NOISE IMMUNITY VERSUS
AMBIENT TEMPERATURE

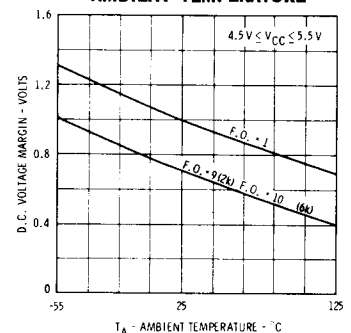


Fig. 5e

**WORST CASE TURN ON DELAY
VERSUS AMBIENT TEMPERATURE
(6k Gates)**

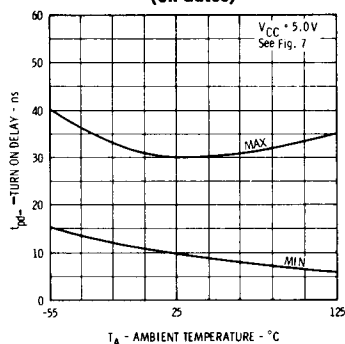


Fig. 5f

**WORST CASE TURN OFF DELAY
VERSUS AMBIENT TEMPERATURE
(6k Gates)**

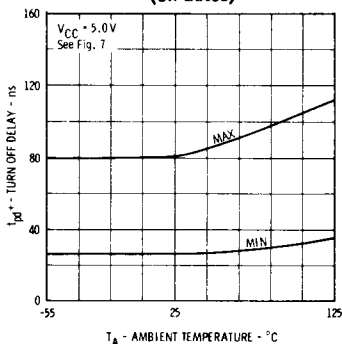


Fig. 5g

**INCREASE OF PROPAGATION
DELAY VERSUS CAPACITANCE
(6k Gates)**

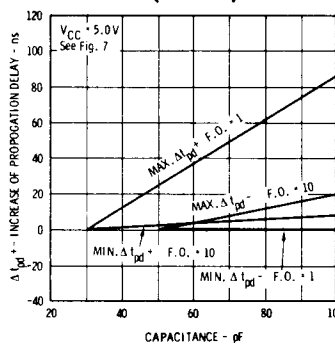


Fig. 5h

**DECREASE OF TURN OFF DELAY
VERSUS FANOUT
(6k Gates)**

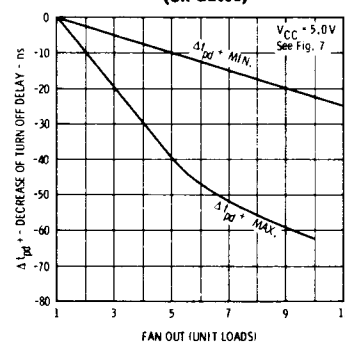


Fig. 5i

**WORST CASE TURN ON DELAY
VERSUS AMBIENT TEMPERATURE
(2k Gates)**

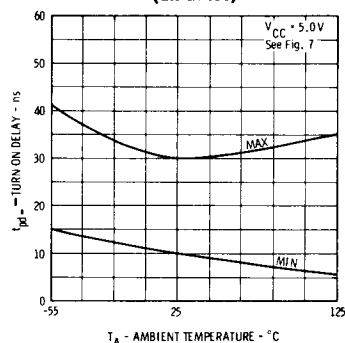


Fig. 5j

**WORST CASE TURN OFF DELAY
VERSUS AMBIENT TEMPERATURE
(2k Gates)**

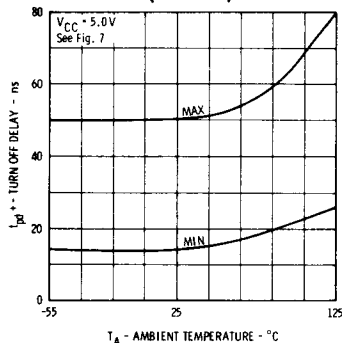


Fig. 5k

**INCREASE OF PROPAGATION
DELAY VERSUS CAPACITANCE
(2k Gates)**

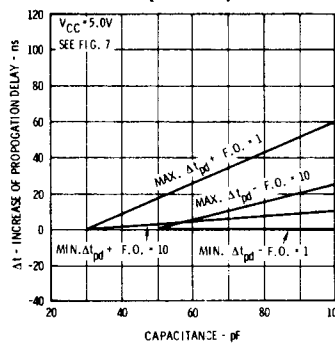
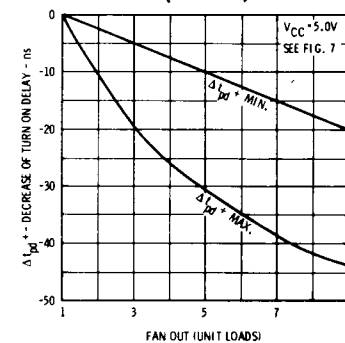


Fig. 5l

**DECREASE OF TURN ON DELAY
VERSUS FANOUT
(2k Gates)**



INPUT AND OUTPUT CHARACTERISTICS

Fig. 6a

**TYPICAL INPUT CURRENT
VERSUS INPUT VOLTAGE
(6k & 2k Gates)**

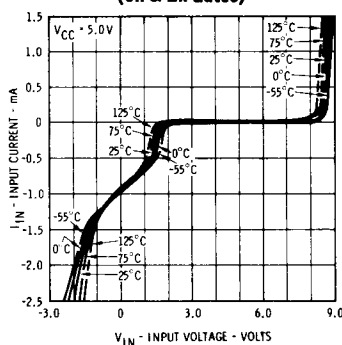


Fig. 6b

**TYPICAL OUTPUT VOLTAGE
VERSUS INPUT VOLTAGE
(6k & 2k Gates)**

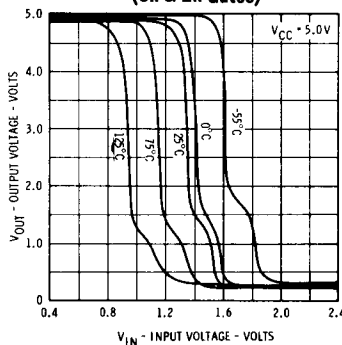


Fig. 6c

**TYPICAL OUTPUT CURRENT
VERSUS OUTPUT VOLTAGE
(6k & 2k Gates)**

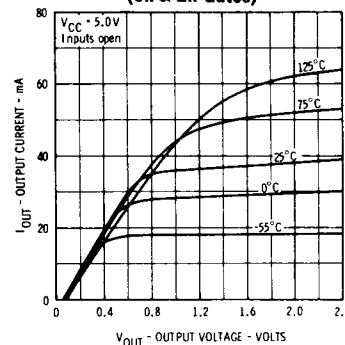


Fig. 6d

**TYPICAL OUTPUT CURRENT
VERSUS OUTPUT VOLTAGE
(2k Gates)**

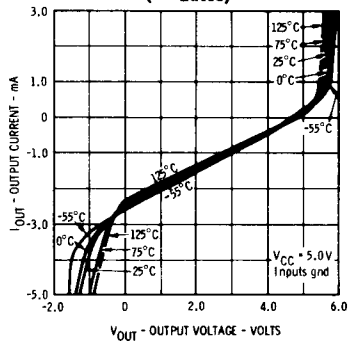
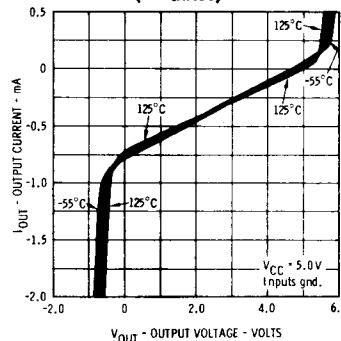


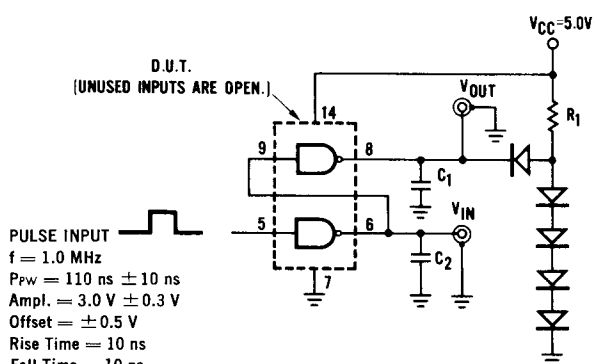
Fig. 6e

**TYPICAL OUTPUT CURRENT
VERSUS OUTPUT VOLTAGE
(6k Gates)**



FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

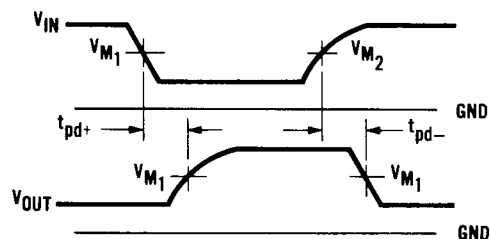
Fig. 7— t_{pd} TEST CIRCUIT AND WAVEFORMS



	t_{pd+}	t_{pd-}
R_1	3.9 k Ω	400 Ω
C_1	30 pF	50 pF
C_2	20 pF	20 pF

Diodes are FD600.

C_1 and C_2 include all jig and probe capacitance

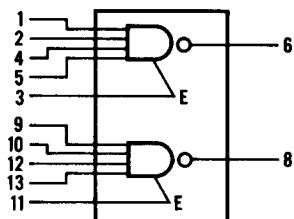


Temp.	V_{m1} (Volts)	V_{m2} (Volts)
-55°C	1.7	1.5
25°C	1.5	1.3
125°C	1.2	1.0

BUFFER ELEMENTS—9932 AND 9944

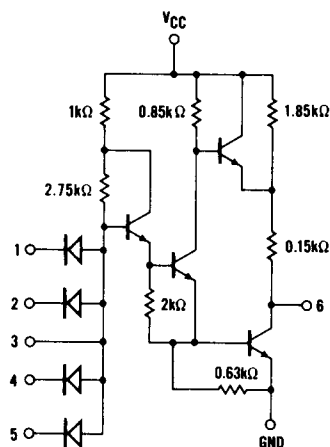
The DT μ L 9932 and DT μ L 9944 are dual “NAND” power gates capable of driving and sinking large currents for high fan-out applications. The DT μ L 9932 features an emitter-follower output pull-up, which provides a high fan-out device with superior capacitance-driving capability. The DT μ L 9944 is intended as a high fan-out gate interface driver, or low power lamp driver.

**Fig. 1—LOGIC DIAGRAM AND
PIN CONFIGURATION
9932, 9944**



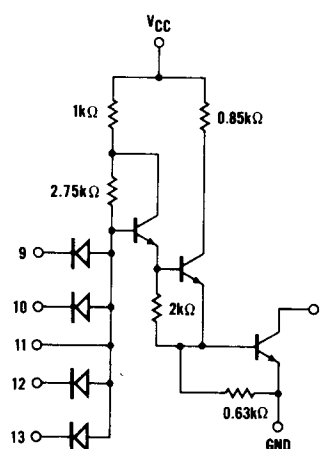
V_{CC} = 14
GND = 7

**Fig. 2—SCHEMATIC DIAGRAM OF THE
DT_μL 9932 ELEMENT
(ONE GATE)**



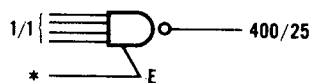
V_{CC} = 14
GND = 7

**Fig. 3—SCHEMATIC DIAGRAM OF THE
DT μ L 9944 ELEMENT
(ONE GATE)**

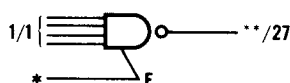


V_{CC} = 14
GND = 7

**Fig. 4—LOADING FACTORS
(9932)**



**Fig. 5—LOADING FACTORS
(9944)**



NOTES:

1. Extender pin (*) allows increased number of inputs by addition of discrete diodes or extender element DT μ L9933.
2. (**) denotes the need for an external resistor to provide high level drive capability. The use of an external resistor will then detract from the low level drive factor as follows: subtract one (1) fan-out for every 3.4 k Ω path from V_{CC} to output.
3. 9932 outputs cannot be wired-OR.

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

TABLE I
ELECTRICAL CHARACTERISTICS — 9932 ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS							UNITS	CONDITIONS	
		−55°C		+25°C			+125°C				
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.			
V _{OH}	Output High Voltage	2.5		2.6	2.8		2.5		Volts	V _{CC} = 4.5 V Inputs at V _{IL} (See Below)	I _{OH} = −2.0 mA at −55°C = −2.5 mA at 25°C = −4.0 mA at 125°C
V _{OL}	Output Low Voltage		0.4		0.27	0.4		0.4	Volts	V _{CC} = 4.5 V, I _{OL} = 36 mA V _{CC} = 5.5 V, I _{OL} = 37.5 mA Inputs at V _{IH} (See Below)	
V _{IH}	Input High Voltage	2.1		1.9			1.7		Volts	Guaranteed Input High Threshold For All Inputs	
V _{IL}	Input Low Voltage		1.4			1.1		0.8	Volts	Guaranteed Input Low Threshold For All Inputs	
I _F	Input Load Current	−1.5		−1.2		−1.5	−1.4		mA	V _{CC} = 5.5 V, V _F = 0.4 V	
		−1.16		−0.93		−1.16	−1.08		mA	V _{CC} = 4.5 V, V _F = 0.4 V	
I _R	Input Leakage Current					2.0	5.0		μA	V _R = 4.0 V Other inputs grounded	
I _{PD} (per gate)	V _{CC} Current “Gate On”					10	13.3		mA	V _{CC} = 5.0 V, Inputs Open	
	V _{CC} Current “Gate Off”					1.15	1.47		mA	V _{CC} = 5.0 V, Inputs Grounded	
t _{pd+}	Turn Off Delay			25	50	80			ns	V _{CC} = 5.0 V, See Page 8, Fig. 7	
t _{pd−}	Turn On Delay			15	25	40			ns		

TABLE II
ELECTRICAL CHARACTERISTICS — 9944 ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS						UNITS	CONDITIONS	
		−55°C		+25°C			+125°C			
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
V _{OL}	Output Low Voltage	0.4		0.27		0.4	0.4		Volts	V _{CC} = 4.5 V, I _{OL} = 36 mA V _{CC} = 5.5 V, I _{OL} = 37.5 mA Inputs at V _{IH} (see below)
V _{IH}	Input High Voltage	2.1		1.9			1.7		Volts	Guaranteed input high threshold for all inputs
V _{IL}	Input Low Voltage	1.4				1.1	0.8		Volts	Guaranteed input low threshold for all inputs
I _{CEX}	Output Leakage	50				100	200		μA	V _{CEX} = 4.5 V Inputs at V _{IL} (see above)
I _F	Input Load Current	−1.5		−1.3		−1.5	−1.4		mA	V _{CC} = 5.5 V, V _F = 0.4 V
		−1.16		−1.0		−1.16	−1.08		mA	V _{CC} = 4.5 V, V _F = 0.4 V
I _R	Input Leakage Current			0.02		2.0	5.0		μA	V _R = 4.0 V Other inputs grounded
I _{PD} (per gate)	V _{CC} Current “Gate On”			7.6		10			mA	V _{CC} = 5.0 V, Inputs Open
	V _{CC} Current “Gate Off”			1.15		1.47			mA	V _{CC} = 5.0 V, Inputs Grounded
t _{pd+}	Turn Off Delay			15	35	50			ns	V _{CC} = 5.0 V, See Page 8, Fig. 8
t _{pd−}	Turn On Delay			10	20	35			ns	

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

9932 AND 9944 ELECTRICAL CHARACTERISTICS

Fig. 6a
WORST CASE POWER DISSIPATION VERSUS AMBIENT TEMPERATURE

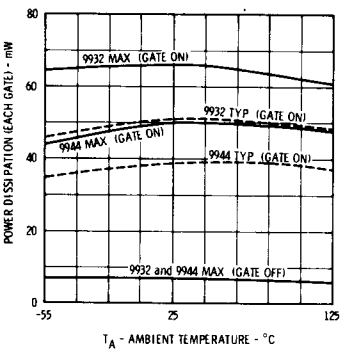


Fig. 6b
WORST CASE LOGIC LEVELS VERSUS AMBIENT TEMPERATURE

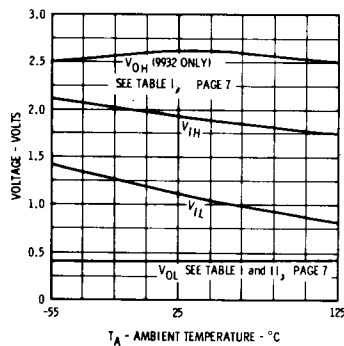


Fig. 6c
WORST CASE HIGH LEVEL NOISE IMMUNITY VERSUS AMBIENT TEMPERATURE (9932 ONLY)

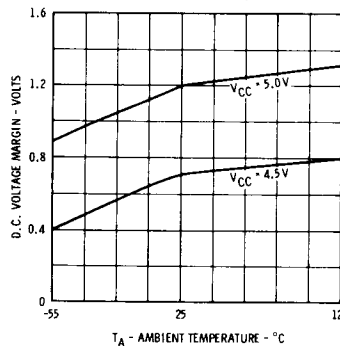


Fig. 6d
WORST CASE LOW LEVEL NOISE IMMUNITY VERSUS AMBIENT TEMPERATURE

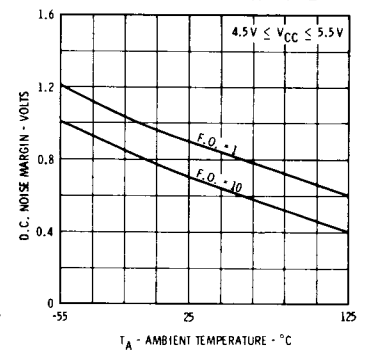


Fig. 6e
TYPICAL INPUT CURRENT VERSUS INPUT VOLTAGE

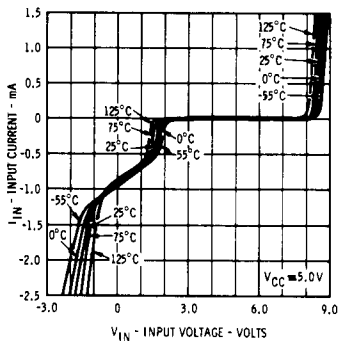


Fig. 6f
TYPICAL OUTPUT VOLTAGE VERSUS INPUT VOLTAGE (9932 ONLY)

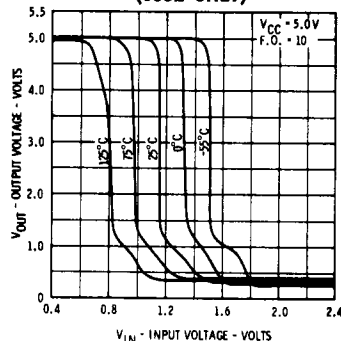


Fig. 6g
TYPICAL OUTPUT CURRENT VERSUS OUTPUT VOLTAGE (9932 ONLY)

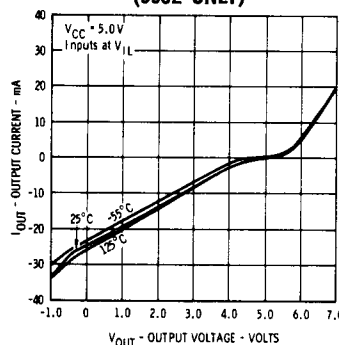
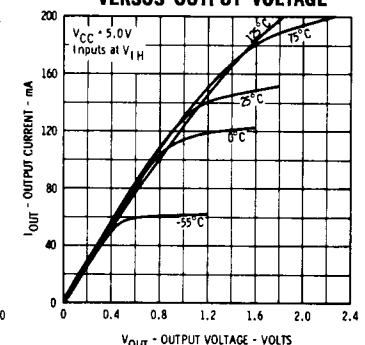
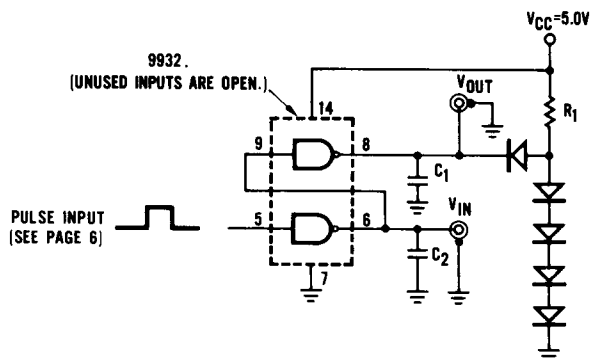


Fig. 6h
TYPICAL OUTPUT CURRENT VERSUS OUTPUT VOLTAGE



SWITCHING CHARACTERISTICS

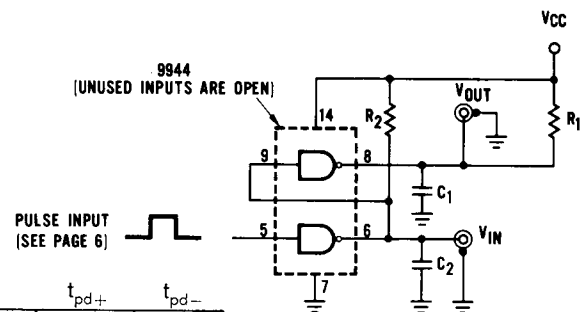
Fig. 7— t_{pd} TEST CIRCUIT FOR DT μ L 9932 ELEMENT



	t_{pd+}	t_{pd-}
R_1	510 Ω	150 Ω
C_1	500 pF	500 pF
C_2	20 pF	20 pF

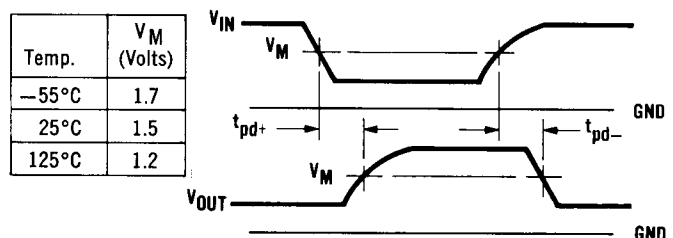
All Diodes are FD600 or Equivalent
C₁ and C₂ include Probe and Jig Capacitance

Fig. 8— t_{pd} TEST CIRCUIT FOR DT μ L 9944 ELEMENT



	t_{pd+}	t_{pd-}
R_1	510 Ω	150 Ω
R_2	2 k Ω	2 k Ω
C_1	20 pF	100 pF
C_2	20 pF	20 pF

Fig. 9—WAVEFORMS FOR 9932 AND 9944



FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

Fig. 10a
WORST CASE TURN ON DELAY
VERSUS AMBIENT TEMPERATURE

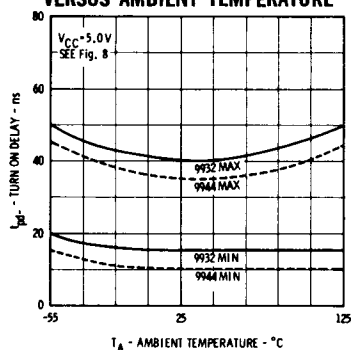


Fig. 10b
WORST CASE TURN OFF DELAY
VERSUS AMBIENT TEMPERATURE

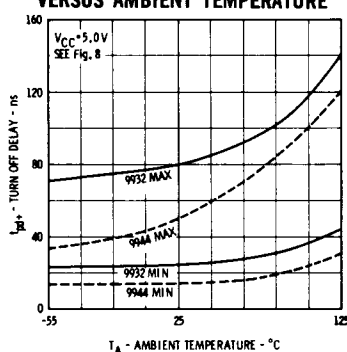
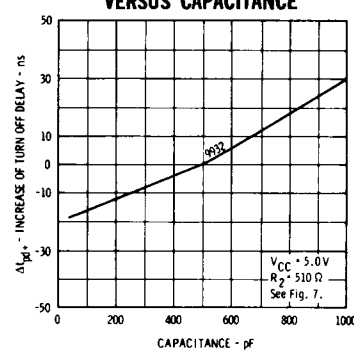


Fig. 10c
INCREASE OF TURN OFF DELAY
VERSUS CAPACITANCE



EXTENDABLE HEX INVERTER — 9935

A 9935 inverter is intended for use with discrete diode expansion of the input. Input load and drive factors can be calculated with the aid of the curves on Page 11 and the forward/reverse characteristics of the diode used.

A single 9935 inverter can be driven directly by the outputs of other DTμL elements, with the exception of 9932 and 9950, providing no more than 5 mA is allowed to flow into the input of the 9935. Commoning 9935 inputs is not a recommended configuration.

When extending inputs with diodes, care should be taken to minimize capacitance on the input node as turn on delay will be increased by 2 ns per picofarad of stray capacitance at this node.

Fig. 1—LOGIC DIAGRAM AND PIN CONFIGURATION

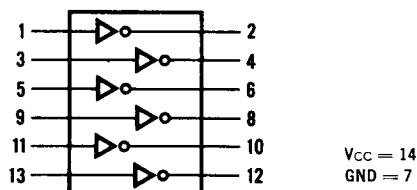
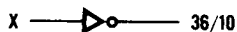


Fig. 3—LOADING FACTORS



X = input to be used with 9933 or discrete diode.

Fig. 2—SCHEMATIC DIAGRAM
(ONE INVERTER ONLY)

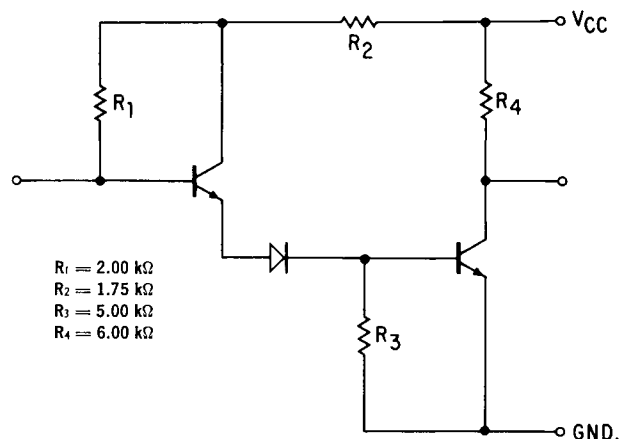


TABLE I

ELECTRICAL CHARACTERISTICS — 9935 ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0 \text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS						UNITS	CONDITIONS	
		-55°C		+25°C		+125°C				
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
V _{OH}	Output High Voltage	2.5		3.5 2.6		2.5		Volts	V _{CC} = 4.5 V, I _{OH} = -0.18 mA Inputs at V _{IL}	
V _{OL}	Output Low Voltage	0.4		0.25 0.4		0.4		Volts	V _{CC} = 4.5 V, I _{OL} = 12 mA V _{CC} = 5.5 V, I _{OL} = 15 mA Inputs at V _{IH}	
V _{IH}	Input High Voltage	2.3		2.0		1.8		Volts	Guaranteed input high threshold with FD600 diode	
V _{IL}	Input Low Voltage	1.4		1.1		0.8		Volts	Guaranteed input low threshold with FD600 diode	
I _F	Input Load Current	-1.5		-1.2 -1.5		-1.5		mA	V _{CC} = 5.5 V, V _F = 0.4 V	
		-1.2		-0.93 -1.2		-1.2		mA	V _{CC} = 4.5 V, V _F = 0.4 V	
I _{PD} (per gate)	V _{CC} Current "Gate On"			2.41 3.1				mA	V _{CC} = 5.0 V, Inputs open	
	V _{CC} Current "Gate Off"			1.33 1.7				mA	V _{CC} = 5.0 V, Inputs gnd.	
t _{pd+}	Turn Off Delay			25 65 80				ns	V _{CC} = 5.0 V, See Page 10, Fig. 5	
t _{pd-}	Turn On Delay			10 30 40				ns		

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

9935 ELECTRICAL CHARACTERISTICS

Fig. 4a
WORST CASE POWER DISSIPATION
VERSUS AMBIENT TEMPERATURE
(EACH INVERTER)

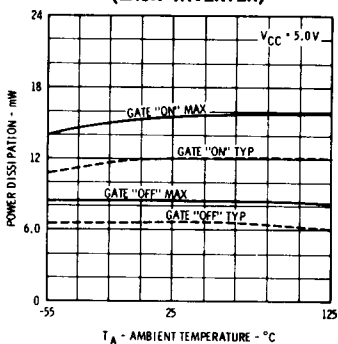


Fig. 4b
WORST CASE LOGIC LEVELS
VERSUS AMBIENT TEMPERATURE

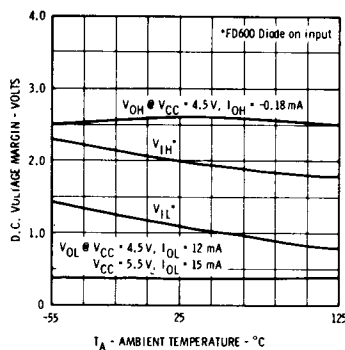


Fig. 4c
HIGH INPUT THRESHOLD
VOLTAGE VERSUS FORWARD
EXTENDER DIODE VOLTAGE

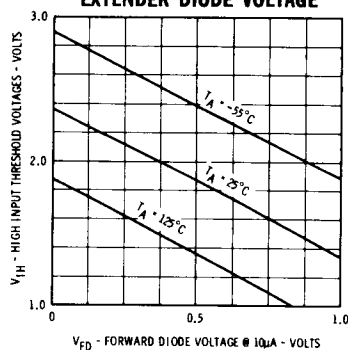


Fig. 4d
WORST CASE HIGH LEVEL
NOISE IMMUNITY VERSUS
AMBIENT TEMPERATURE

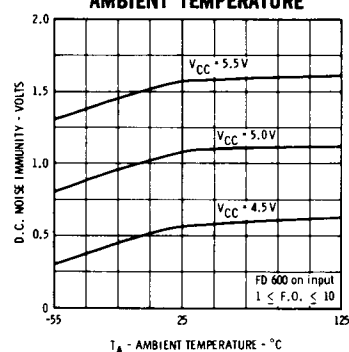


Fig. 4e
WORST CASE LOW LEVEL
NOISE IMMUNITY VERSUS
AMBIENT TEMPERATURE

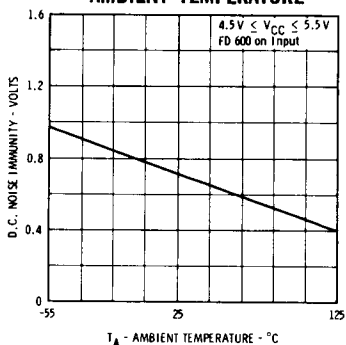


Fig. 4f
LOW INPUT THRESHOLD
VOLTAGE VERSUS
FORWARD DIODE VOLTAGE

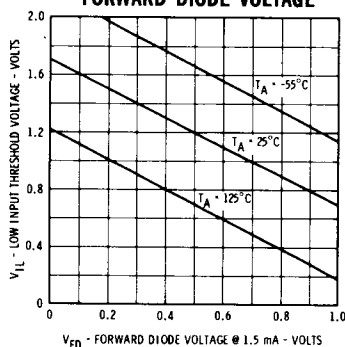


Fig. 4g
WORST CASE TURN OFF DELAY
VERSUS AMBIENT TEMPERATURE

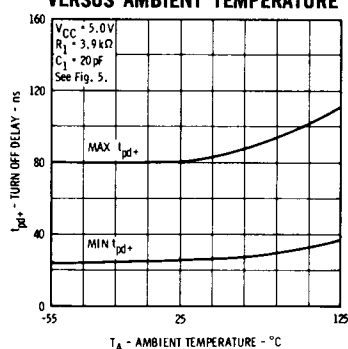


Fig. 4h
WORST CASE TURN ON DELAY
VERSUS AMBIENT TEMPERATURE

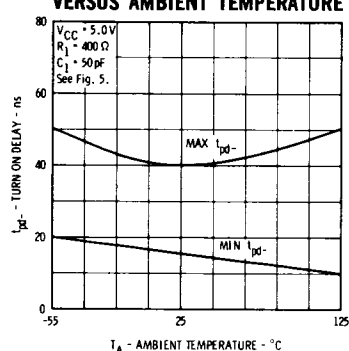
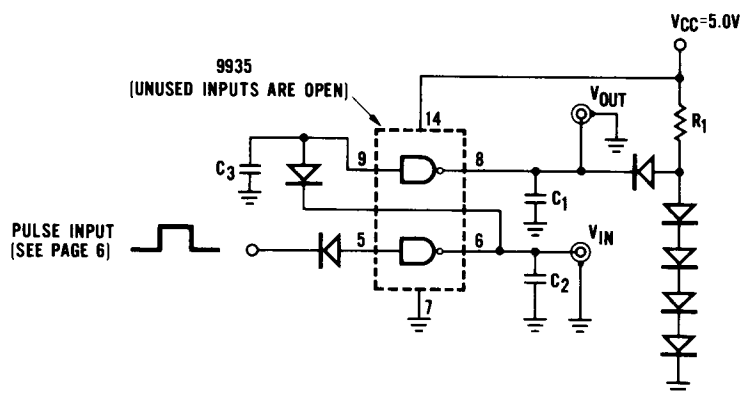


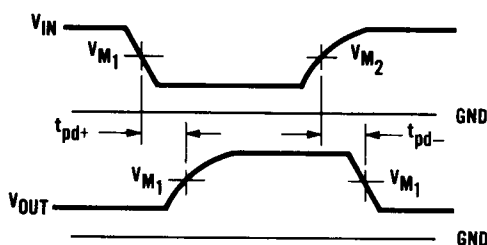
Fig. 5—SWITCHING TIME TEST CIRCUIT



	t_{pd+}	t_{pd-}
R_1	3.9 k	400 Ω
C_1	30 pF	50 pF
C_2	20 pF	20 pF
C_3	5 pF	5 pF

Diodes are FD600 or equivalent

C_1 and C_2 include jig and Probe Capacitance



Temp.	V_{M1} (Volts)	V_{M2} (Volts)
-55°C	1.7	1.5
+25°C	1.5	1.3
+125°C	1.2	1.0

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

DT μ L EXTENDER ELEMENT—9933

The DT μ L 9933 is a dual four-input extender element. DT μ L 9933 elements may be used to extend fan-in capability to more than 20 without adversely affecting the noise immunity or load driving capability of the element to which they are connected. Typical input capacitance of DT μ L 9933 is 2.0 pF and output capacitance is 5.0 pF.

Fig. 1—LOGIC DIAGRAM AND PIN CONFIGURATION

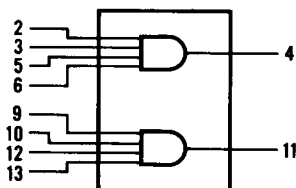
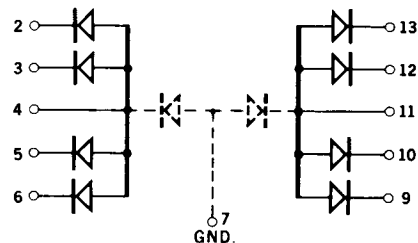
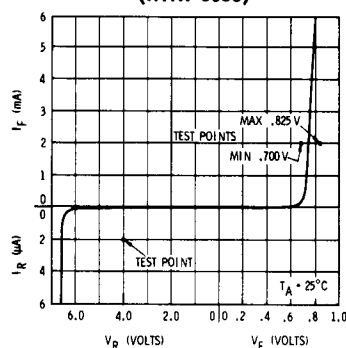


Fig. 2—SCHEMATIC DIAGRAM

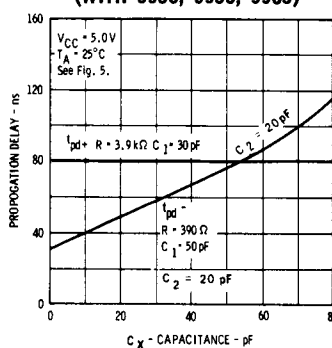


9933 ELECTRICAL CHARACTERISTICS

**Fig. 3a
TYPICAL FORWARD AND
REVERSE CHARACTERISTICS
(WITH 9933)**



**Fig. 4a
WORST CASE PROPAGATION
DELAY VERSUS EXTENDER PIN
CAPACITANCE
(WITH 9930, 9935, 9963)**



**Fig. 4b
WORST CASE PROPAGATION
DELAY VERSUS EXTENDER PIN
CAPACITANCE
(WITH 9932)**

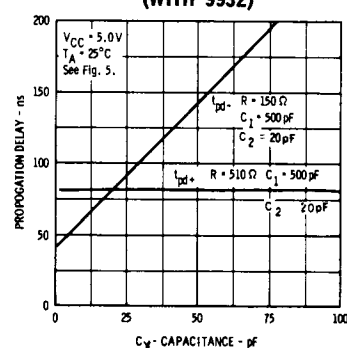
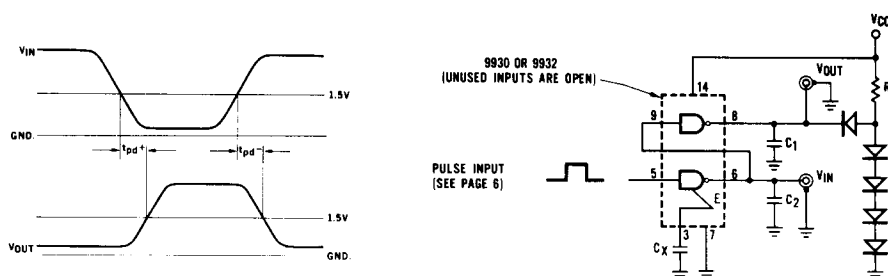


Fig. 5—WAVEFORMS AND TEST CIRCUIT

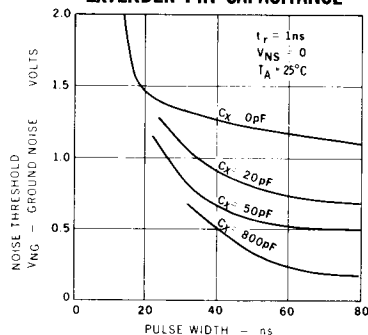


Diodes are FD600

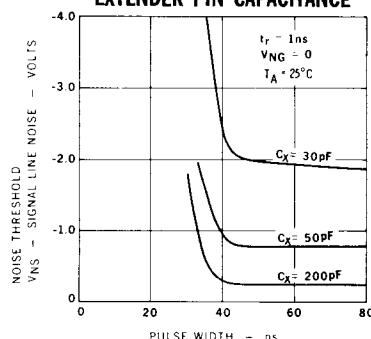
C_X represents the summation of the DT μ L 9933 Dual Extender Element output capacitances (~ 5.0 pF per output) and associated board, connector and wiring capacitances.

Typical Curves to Show the Effects of Extender Pin Capacitance on Noise Threshold of DT μ L9930 Dual Gate

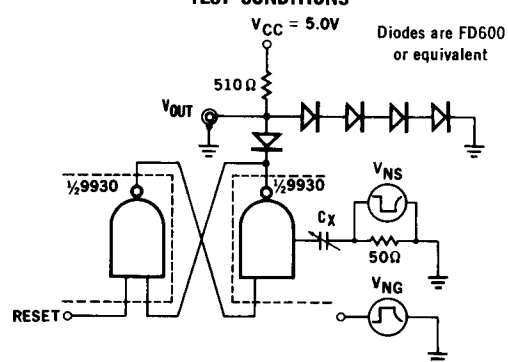
**Fig. 6a
PULSED GROUND NOISE
THRESHOLD AS A FUNCTION OF
EXTENDER PIN CAPACITANCE**



**Fig. 6b
PULSED SIGNAL LINE NOISE
THRESHOLD AS A FUNCTION OF
EXTENDER PIN CAPACITANCE**



**Fig. 6c
TEST CONDITIONS**



FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

R-S FLIP-FLOPS 9945, 9948 AND 9111 DUAL J-K FLIP-FLOPS 9093, 9094, 9097 AND 9099

GENERAL DESCRIPTION

The DT μ L 9930 series has seven flip-flops to satisfy the storage requirements of a logic system. Four flip-flops are dual J-K designs with buffered outputs, allowing the wired-OR configuration to be used. The other three flip-flops operate in the R-S mode and can be converted to J-K operation with external cross-coupled connections. All flip-flops incorporate the master-slave design which offers the advantage of a D.C. threshold on the clock input initiating the transition of the outputs, so that careful control of the clock pulse rise and fall times is not required.

Data is accepted by the master flip-flop while the clock is high. Refer to truth table for definition of "one" and "zero" levels. Transfer from the master flip-flop to the slave flip-flop occurs on the high to low transition of the clock. When the clock is low, the J, K, S, and C inputs are inhibited.

The asynchronous inputs provide ability to control the state of the flip-flop independent of static conditions on the clock and synchronous inputs. Both asynchronous set and clear are provided on the 9945, 9948, 9097 and 9099. The 9093 and 9094 have only asynchronous set inputs, and the 9111 has only asynchronous clear inputs.

LOGIC DIAGRAMS AND LOADING FACTORS

Fig. 1—9945

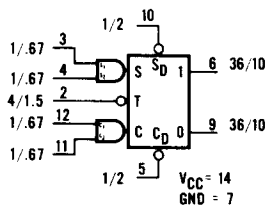


Fig. 3—9948

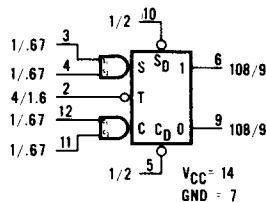


Fig. 5—9111

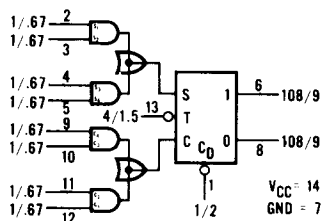


Fig. 7 9945/9948 (J-K MODE)

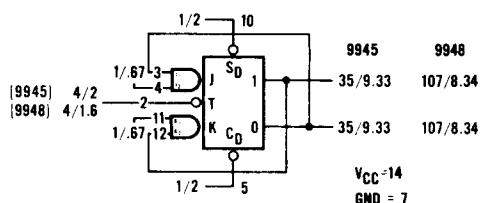


Fig. 2—9093

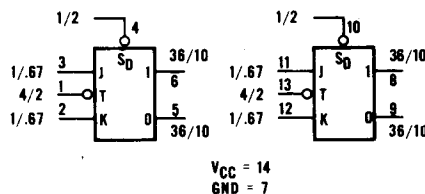


Fig. 4—9094

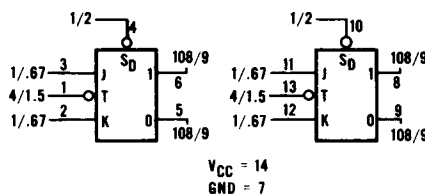


Fig. 6—9097

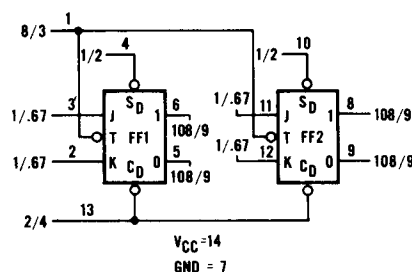
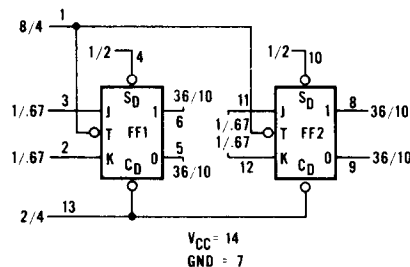


Fig. 8 9099



FUNCTIONAL LOGIC DIAGRAMS

Fig. 9—9945, 9948 AND 9111

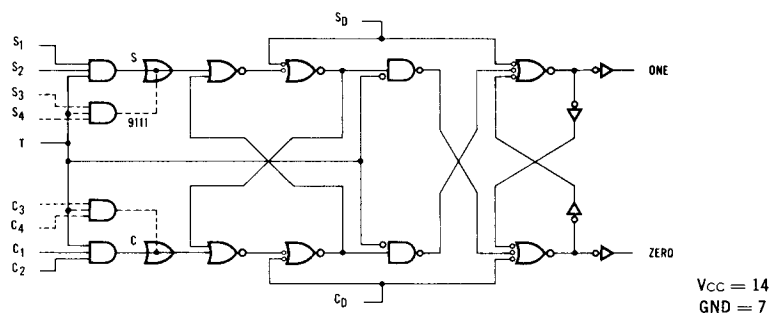
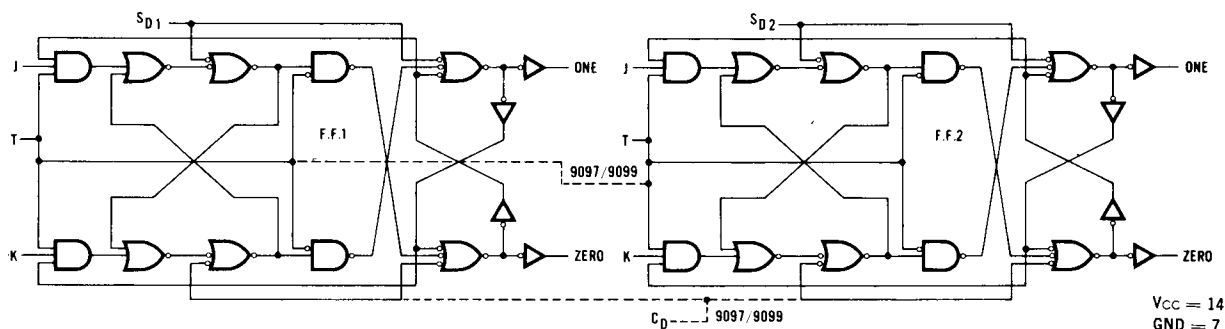


Fig. 10—9093, 9094, 9097 AND 9099



SYNCHRONOUS OPERATION

The truth table defines the next state of the flip-flop after a high to low transition of the clock pulse. The output of all flip-flops operating in the J-K mode is a function of the previous state of the flip-flop and the condition of the inputs prior to a high to low transition of the clock. The output of all flip-flops operating in the R-S mode is a function of the S and C inputs at the time of a high to low clock transition.

The S and C inputs in the table refer to the basic S and C inputs as indicated on the logic diagrams of the 9945, 9948, and 9111. These internal inputs are the result of a logic operation on the external S and C inputs. This operation is represented symbolically by "AND" gates in the logic diagram for each flip-flop. Logic diagrams are in accordance with MIL STANDARD 806B.

The L* symbol in the J, K, C, and S input columns is defined as that input does not go high at any time while the clock is high.

The H* symbol in the J, K, C, and S input columns is defined as that the input is high at some time while the clock is high.

The X symbol indicates that the condition of that input or output has no effect on the next state of the flip-flop.

The H and L symbols refer to steady state high and low voltage levels, respectively.

TABLE I
SYNCHRONOUS OPERATION
R-S FLIP-FLOP

BEFORE CLOCK				OUTPUTS AFTER	
ONE	ZERO	S	C	ONE	ZERO
ONE	ZERO	L*	L*	L	H
L	H	L*	L*	H	L
H	L	L*	L*	L	H
X	X	H*	L	H	L
X	X	H	H	Undetermined	

TABLE II
SYNCHRONOUS OPERATION
J-K FLIP-FLOP

BEFORE CLOCK				OUTPUTS AFTER	
ONE	ZERO	J	K	ONE	ZERO
ONE	ZERO	L*	X	L	H
L	H	L*	X	H	L
L	H	X	L*	H	L
H	L	X	H*	L	H

TABLE III
ASYNCHRONOUS OPERATION

INPUTS		OUTPUTS	
S _D	C _D	ONE	ZERO
L	L	H	H
L	H	H	L
H	L	L	H
H	H	State determined by synchronous inputs and clock input	

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

ELECTRICAL CHARACTERISTICS—BINARY ELEMENTS ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS						UNITS	CONDITIONS & COMMENTS		
		-55°C		+25°C		+125°C					
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.			
V _{OH}	Output High Voltage (9945, 9093, 9099) (9948, 9094, 9097, 9111)	2.5		2.5	3.3		2.5		Volts	V _{CC} = 4.5 V, I _{OH} = -180 μA V _{CC} = 4.5 V, I _{OH} = -540 μA	
V _{OL}	Output Low Voltage (9945, 9093, 9099) (9948, 9094, 9097, 9111)		0.4		0.25	0.4		0.4	Volts	V _{CC} = 4.5 V, I _{OL} = 12.0 mA V _{CC} = 5.5 V, I _{OL} = 15.0 mA V _{CC} = 4.5 V, I _{OL} = 13.0 mA (@ -55°C) V _{CC} = 5.5 V, I _{OL} = 13.6 mA	
V _{IH}	Input High Voltage	2.1		1.9			1.7		Volts	Guaranteed input high threshold for all inputs	
V _{IL}	Input Low Voltage		1.4			1.1		0.8	Volts	Guaranteed input low threshold for all inputs	
I _R	Input Leakage, all J-K S, C, S _D , C _D inputs (except C _D of 9097, 9099)					2.0		5.0	μA	V _{CC} = 5.5 V, V _R = 4.0 V Gnd on other inputs	
	Input Leakage of C _D (9097, 9099)					4.0		10			
I _{RCP}	Input Leakage, CP inputs (9945, 9948, 9093, 9094, 9111) (9097, 9099)					10 20		20 40			
I _F	Input Current, all J, K, S, C inputs		-0.98		-0.82	-0.98		-0.92	mA	V _{CC} = 5.5 V V _F = 0.4 V 4.0 V on other inputs	
	Input Current, S _D or C _D (9093, 9094, 9111)		-2.2		-1.8	-2.2		-1.93			
	Input Current, CP inputs (9945, 9093)		-2.93		-2.40	-2.93		-2.57			
	(9948, 9094)		-2.35		-1.93	-2.35		-2.03			
	(9111)		-3.76		-3.00	-3.76		-3.76			
	(9097)		-4.68		-3.84	-4.68		-4.04			
	(9099)		-5.86		-4.81	-5.86		-5.14			
I _F	Input Current, all J, K, S, C inputs		-0.76		-0.62	-0.76		-0.72	mA	V _{CC} = 4.5 V V _F = 0.4 V 4.0 V on other inputs	
	Input Current, S _D or C _D inputs (9093, 9094, 9111)		-1.7		-1.39	-1.7		-1.5			
	Input Current, CP inputs (9945, 9093)		-2.26		-1.85	-2.26		-2.02			
	(9948, 9094)		-1.83		-1.50	-1.83		-1.59			
	(9111)		-2.90		-2.48	-2.90		-2.88			
	(9097)		-3.66		-3.00	-3.66		-3.18			
	(9099)		-4.52		-3.70	-4.52		-4.04			
I _{FSI}	Input Current, C _D , S _D inputs (9945, 9948, 9097, 9099)		-2.93 -2.26		-2.40 -1.85	-2.93 -2.26		-2.57 -2.20	mA	V _{CC} = 5.5 V V _{CC} = 4.5 V	V _F = 0.4 V 4.0 V on other inputs
I _{PD}	V _{CC} Current (9945) (9948) (9111) (9093) (9094) (9097) (9099)				8.3 9.9 12.1 16.6 19.8 19.8 16.6	14.0 16.2 18.0 28.0 32.4 32.4 28.0			mA	V _{CC} = 5.0 V, all inputs open Momentary ground on S _D	

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

INPUT AND OUTPUT CHARACTERISTICS OF BINARY ELEMENTS

Fig. 11
TYPICAL OUTPUT CURRENT
VERSUS OUTPUT VOLTAGE
(OUTPUT LOW)

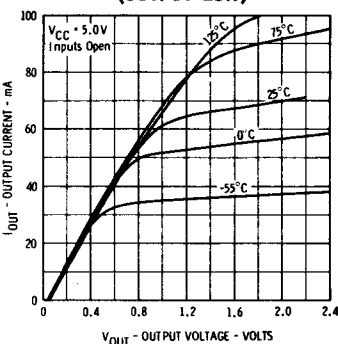


Fig. 12
OUTPUT CURRENT VERSUS
OUTPUT VOLTAGE
(OUTPUT HIGH)

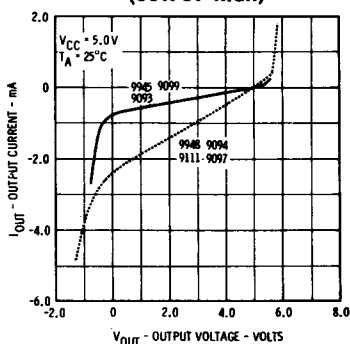


Fig. 13
CLOCK INPUT CURRENT VERSUS
CLOCK INPUT VOLTAGE
(9945, 9093, 9099)

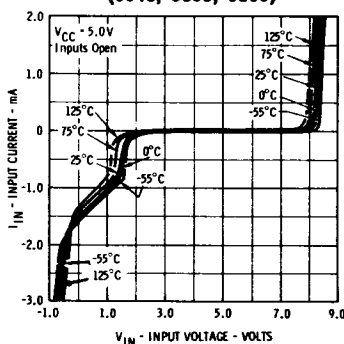


Fig. 14
INPUT CURRENT VERSUS
INPUT VOLTAGE - CLOCK INPUT
(9948, 9094)

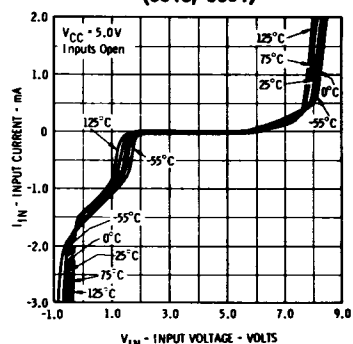


Fig. 15
INPUT CURRENT VERSUS
INPUT VOLTAGE CLOCK INPUT
(9111)

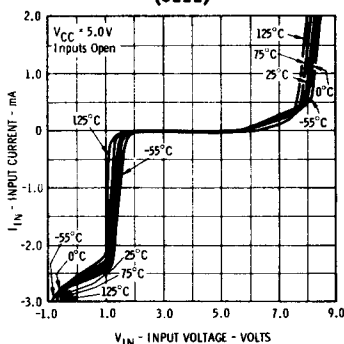


Fig. 16
INPUT CURRENT VERSUS
INPUT VOLTAGE CLOCK INPUT
(9097)

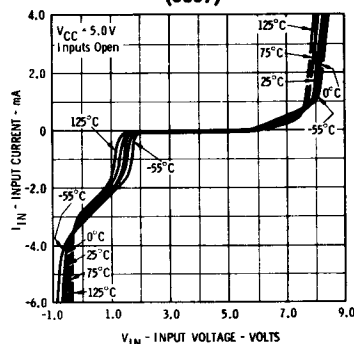


Fig. 17
CLOCK INPUT CURRENT VERSUS
CLOCK INPUT VOLTAGE
(9099)

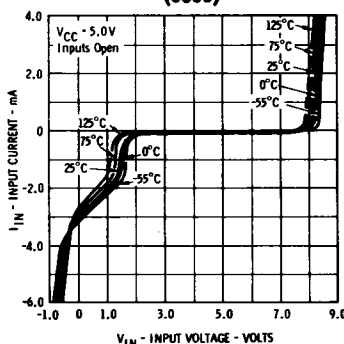


Fig. 18
INPUT CURRENT VERSUS
INPUT VOLTAGE
SYNCHRONOUS INPUTS

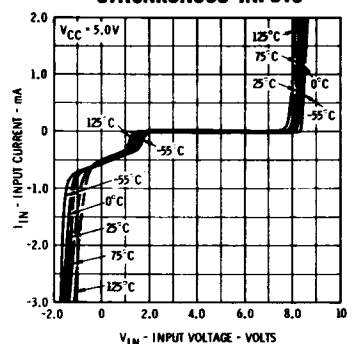


Fig. 19
INPUT CURRENT VERSUS
INPUT VOLTAGE
ASYNCHRONOUS INPUTS

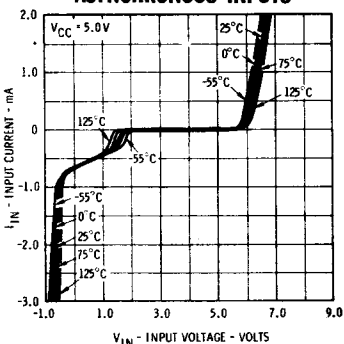


Fig. 20
OUTPUT VOLTAGE VERSUS
CLOCK INPUT VOLTAGE
(9945, 9093, 9099)

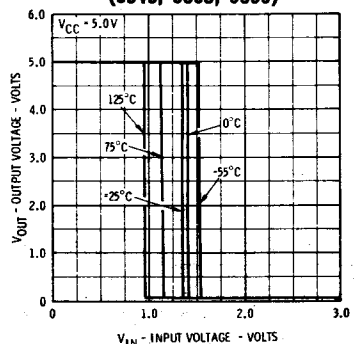


Fig. 21
OUTPUT VOLTAGE VERSUS
CLOCK INPUT VOLTAGE
(9948, 9094, 9097)

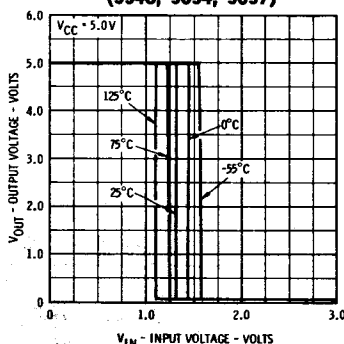
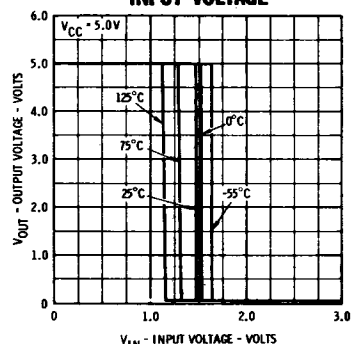


Fig. 22
OUTPUT VOLTAGE VERSUS
ASYNCHRONOUS
INPUT VOLTAGE



SWITCHING CHARACTERISTICS ($T_A = 25^\circ\text{C}$, $V_{CC} = 5.0\text{V}$)

SYMBOL	CHARACTERISTIC	9094, 9097, 9111 and 9948			9093, 9099 and 9945			UNITS	FIGURES
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
t_{pd+}	Clock to Output	30		65	35		75	ns	28, 29, 30
t_{pd-}	Clock to Output	30		75	30		75	ns	
t_{set-up}		35	22		35	22		ns	
$t_{release}$			14	10		14	10	ns	

Fig. 23

**WORST CASE TURN OFF DELAY
VERSUS AMBIENT TEMPERATURE**

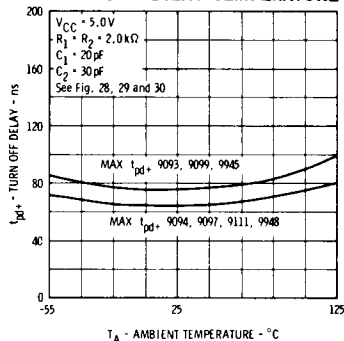


Fig. 24

**WORST CASE TURN ON DELAY
VERSUS AMBIENT TEMPERATURE**

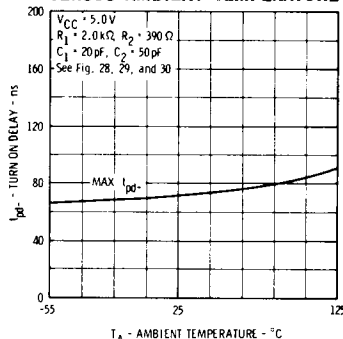


Fig. 25

**WORST CASE INCREASE OF
PROPAGATION DELAY
VERSUS CAPACITANCE**

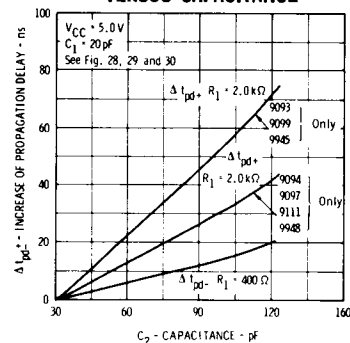


Fig. 26

**DECREASE OF TURN OFF
DELAY VERSUS FANOUT**

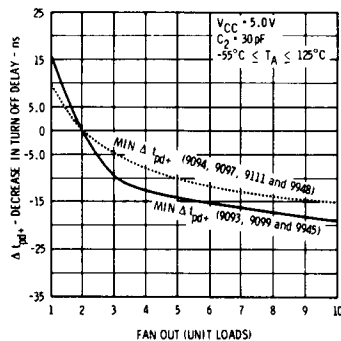
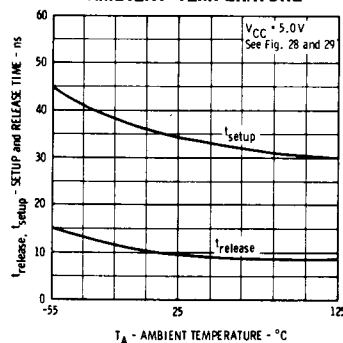


Fig. 27

**WORST CASE SET UP AND
RELEASE TIME VERSUS
AMBIENT TEMPERATURE**



SWITCHING TEST CIRCUITS, $T_A = 25^\circ\text{C}$, $V_{CC} = 5.0\text{V}$

Fig. 28—9945 AND 9948

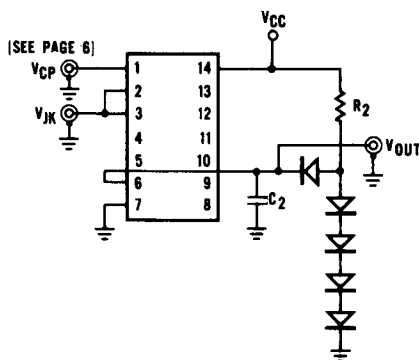


Fig. 29—9093, 9094, 9097 AND 9099

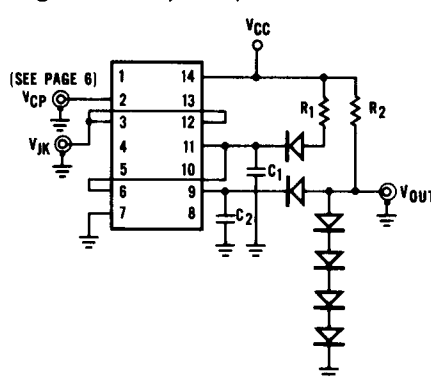


Fig. 30—9111

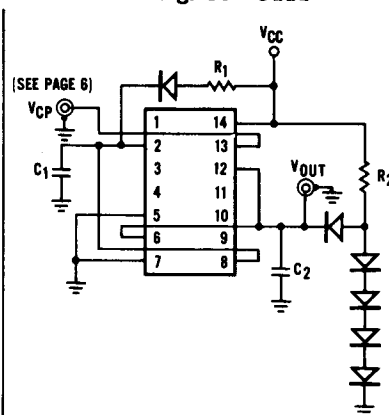
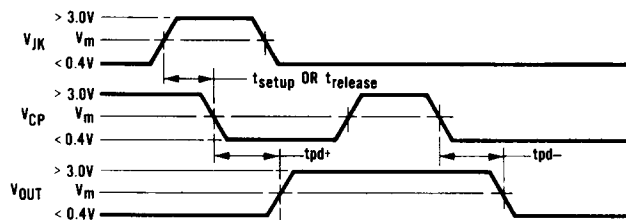


Fig. 31—WAVEFORMS

LOADS		
	t_{pd+}	t_{pd-}
R_1	2.0 kΩ	2.0 kΩ
R_2	2.0 kΩ	390 Ω
C_1	20 pF	20 pF
C_2	30 pF	50 pF

MEASURING VOLTAGE
THRESHOLDS (V_{in})

Temp	V_m
-55°C	1.7 V
25°C	1.5 V
125°C	1.2 V



All capacitances include probe and jig capacitance
All diodes FD600 or equivalent

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

SWITCHING TEST NOTES

t_{pd+} and t_{pd-}

Drive the clock pulse input with a suitable pulse source. t_{pd+} and t_{pd-} delays are defined in the waveforms Fig. 31.

t_{set-up}

1. t_{set-up} is defined as the minimum time required for a HIGH to be present at a synchronous logic input at any time during the high state of the clock in order for the flip-flop to respond to the data.
2. The test for t_{set-up} is performed by adjusting the timing relationship between the V_{CP} and V_{JK} pulse to the t_{set-up} minimum value. A device that passes the test will have the output waveform shown in Fig. 31. The output of a device that does not pass the t_{set-up} test will remain at a static level (no switching will occur).

$t_{release}$

1. $t_{release}$ is defined as the maximum time allowed for a high to be present at a synchronous logic input at any time during the high state of the clock and not be recognized.
2. The test for $t_{release}$ is performed by adjusting the timing relationship between V_{CP} and V_{JK} to the $t_{release}$ maximum value. The outputs of devices that pass will remain at static logic levels. In order to check both J and K sides of the flip-flop it is necessary to perform the test with the flip-flop in each of its two possible states, i.e., set and clear. This can be accomplished by making use of the appropriate direct inputs to establish the state before a test. The outputs of devices that do not pass the $t_{release}$ test will exhibit pulses instead of static levels.

Fig. 32—RECOMMENDED INPUT PULSE SOURCES

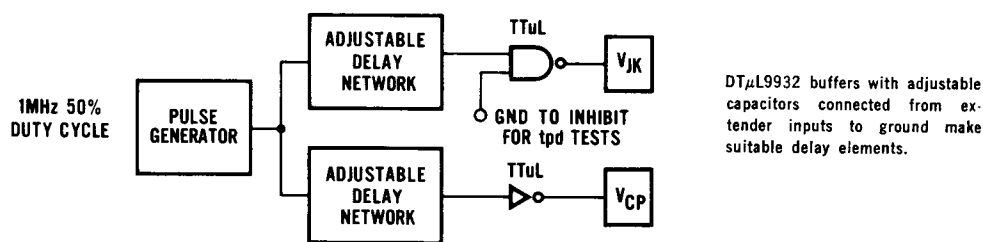


Fig. 33—9945 AND 9948 SCHEMATIC DIAGRAM

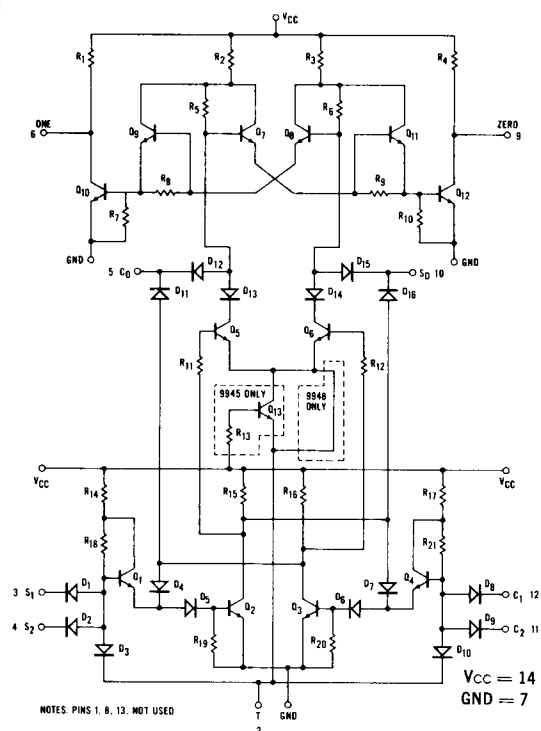
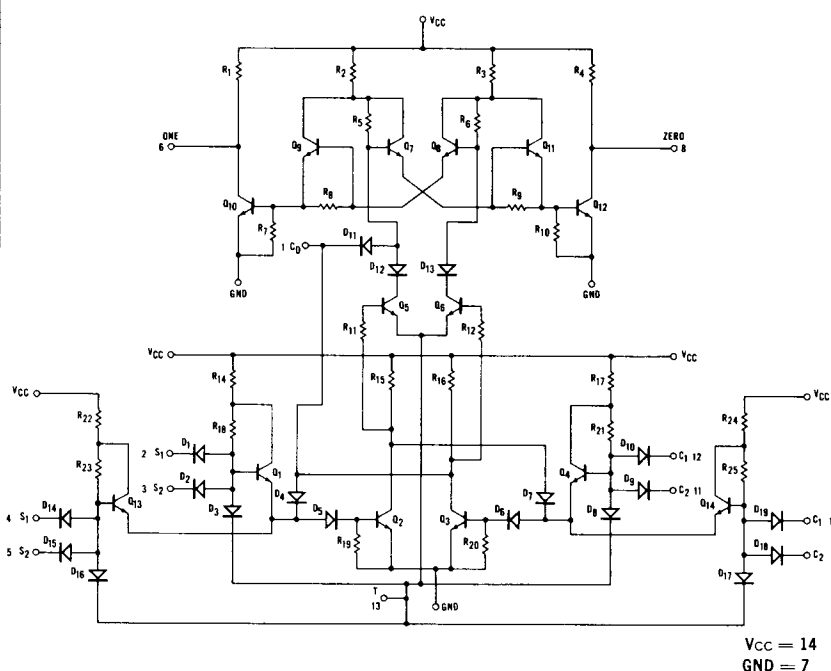


Fig. 34—9111 SCHEMATIC DIAGRAM



RESISTOR VALUES 9945, 9948 AND 9111

$R_1, R_4 = 6.0 \text{ k}\Omega$ (9945)	$R_7, R_{10} = 1.2 \text{ k}\Omega$
$= 2.0 \text{ k}\Omega$ (9948, 9111)	$R_8, R_9 = 3.0 \text{ k}\Omega$
$R_2, R_3 = 2.2 \text{ k}\Omega$	$R_{11}, R_{12}, R_{19}, R_{20} = 9.0 \text{ k}\Omega$
$R_5, R_6, R_{18}, R_{21}, R_{23}, R_{25} = 3.5 \text{ k}\Omega$	$R_{13} = 10 \text{ k}\Omega$
$R_{15}, R_{16} = 3.2 \text{ k}\Omega$	$R_{14}, R_{17}, R_{22}, R_{24} = 2.5 \text{ k}\Omega$

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

SCHEMATIC DIAGRAMS

Fig. 35—9093 AND 9094

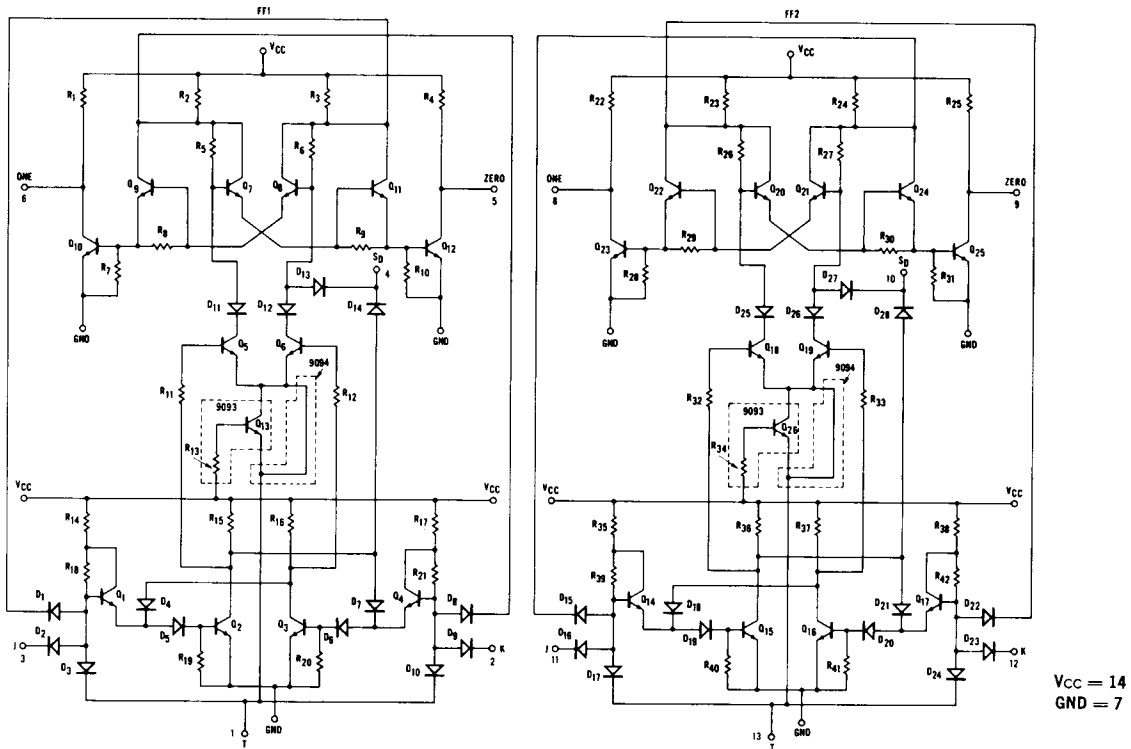
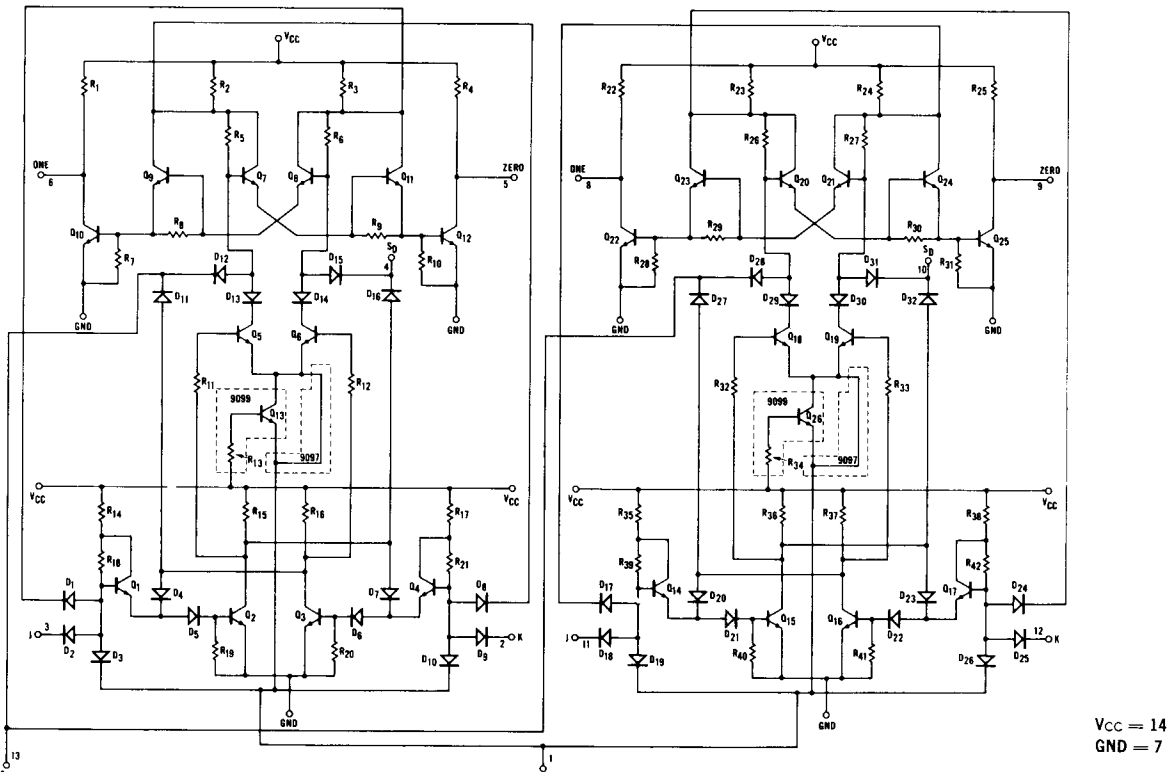


Fig. 36—9097 AND 9099



Resistor Values: 9093, 9094, 9097, 9099

R1, R4, R22, R25 = 6.0 kΩ (9093, 9099)
= 2.0 kΩ (9094, 9097)

R2, R3, R23, R24 = 2.2 kΩ

R5, R6, R18, R21, R26, R27, R39, R42 = 3.5 kΩ

R7, R10, R28, R31 = 1.2 kΩ

R8, R9, R29, R30 = 3.0 kΩ

R11, R12, R19, R20, R32, R33, R40, R41 = 9.0 kΩ

R13, R26 = 10 kΩ

R14, R17, R35, R38 = 2.5 kΩ

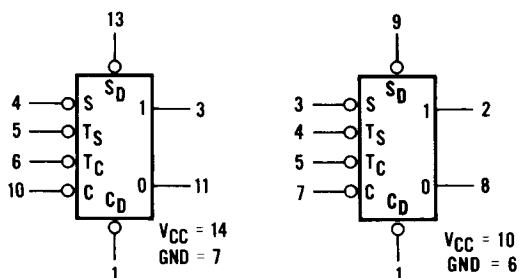
R15, R16, R36, R37 = 3.2 kΩ

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

BINARY ELEMENT — 9950

The DT μ L 9950 is an A-C coupled R-S flip-flop.

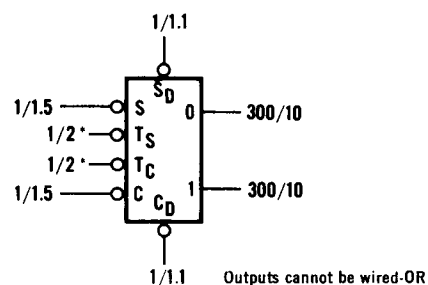
Fig. 1—LOGIC DIAGRAM AND PIN CONFIGURATION



14 PIN DIP OR FLATPACK

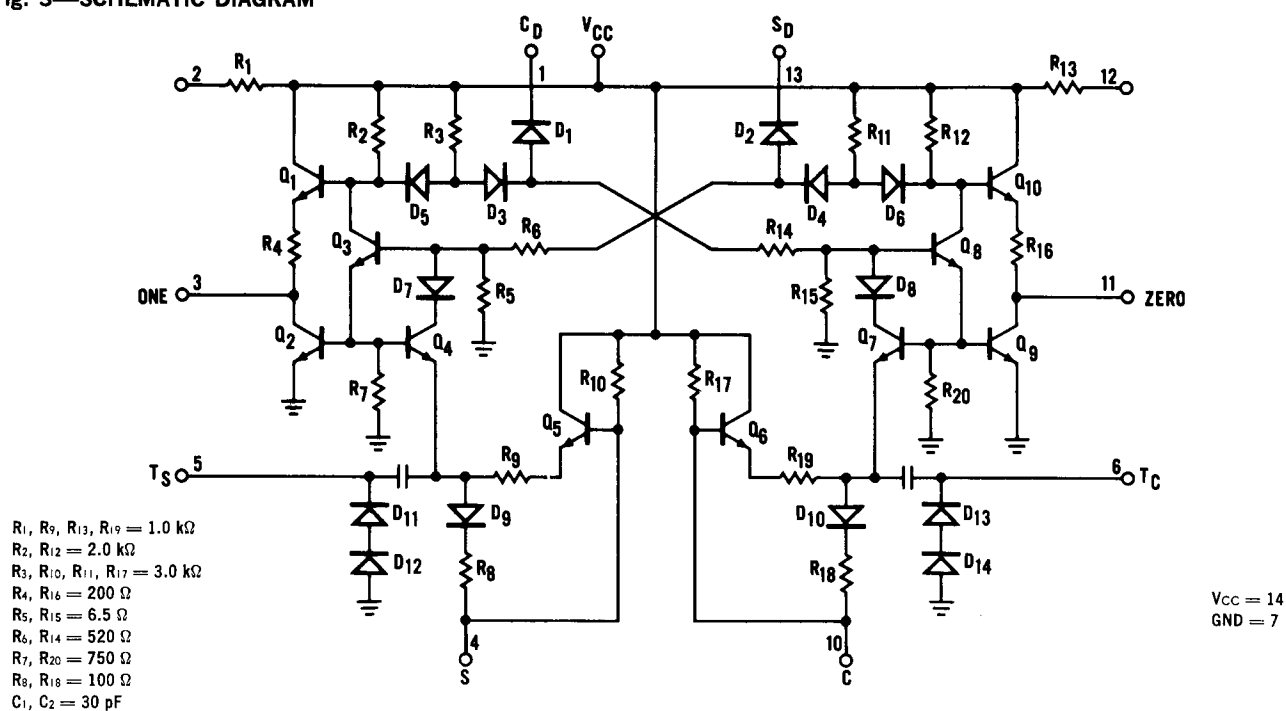
TO-100 PACKAGE

Fig. 2—LOADING RULES



* CAPACITIVE INPUTS

Fig. 3—SCHEMATIC DIAGRAM



TRUTH TABLE — TABLE I

RESPONSE TO							
PULSE INPUTS				DIRECT INPUTS			
4	5	6	10	3	11	1	13
INPUTS	OUTPUTS	INPUTS	OUTPUTS	INPUTS	OUTPUTS	INPUTS	OUTPUTS
H	X	H	X	NC	NC	H	H
X	H	X	H	NC	NC	L	H
L	L	X	H	H	L	H	L
L	L	H	X	H	L	L	L
H	X	L	L	L	H		
X	H	L	L	L	H		
L	L	L	L	AMBIGUOUS			

NOTES:

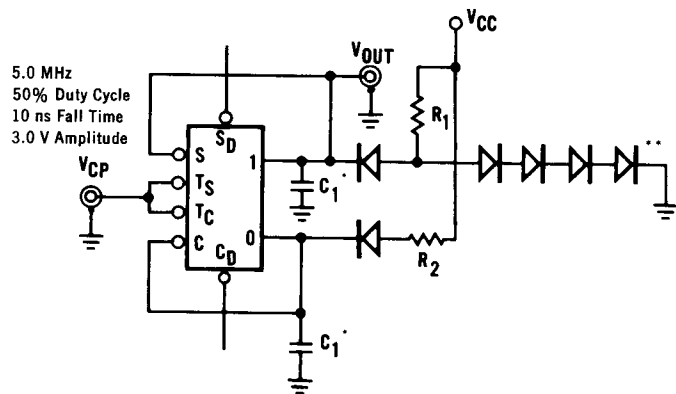
- Abbreviations used in the body of tables:
 L = low, the more negative voltage level
 H = high, the more positive voltage level
 (in all cases, open pins have the same effect as high.)
 X = immaterial, either H or L has equal effect
 NC = no change, the trigger-pulse has no effect on outputs
- H or L for pins 5 and 6 represent voltage transitions to the level indicated rather than the levels themselves.
- The tables assume independent use of pulsed inputs and direct inputs. Otherwise, direct inputs will predominate.

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

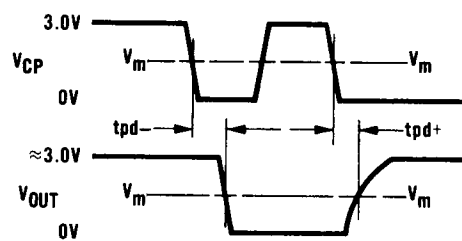
TABLE I —
ELECTRICAL CHARACTERISTICS 9950 ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS							UNITS	CONDITIONS
		-55°C		+25°C			+125°C			
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
V _{OH}	Output High Voltage	2.5		2.6			2.5		Volts	V _{CC} = 4.5 V, I _{OH} = -1.5 mA
V _{OL}	Output Low Voltage		0.4			0.4		0.4	Volts	V _{CC} = 4.5 V, I _{OL} = 12 mA V _{CC} = 5.5 V, I _{OL} = 15 mA
V _{IHS}	Asynchronous Input High Voltage	2.1		1.9			1.7		Volts	Guaranteed high threshold for asynchronous inputs
V _{ILS}	Asynchronous Input Low Voltage		.95			.80		.605	Volts	Guaranteed low threshold for asynchronous inputs
I _R	Input Leakage					2.0		5.0	μA	V _{CC} = 5.5 V, V _R = 4.0 V Asynchronous inputs only
I _F	Input Load Current		-2.22			-2.22		-2.09	mA	V _{CC} = 5.5 V, V _F = 0.4 V
I _F	Input Load Current		-1.83			-1.83		-1.71	mA	V _{CC} = 4.5 V, V _F = 0.4 V
I _{FSI}	Asynchronous Input Load Current		-1.64			-1.64		-1.46	mA	V _{CC} = 5.5 V, V _F = 0.4 V
I _{FSI}	Asynchronous Input Load Current		-1.20			-1.24		-1.14	mA	V _{CC} = 4.5 V, V _F = 0.4 V
I _{PD}	V _{CC} Current		8.7		6.7	8.7		8.7	mA	V _{CC} = 5.0 V, Input 4 gnd.
t _{pd+}	Turn Off Delay					30			ns	V _{CC} = 5.0 V
t _{pd-}	Turn On Delay					30			ns	See Fig. 4
	Toggling Frequency			20					MHz	

Fig. 4— t_{pd} TEST CIRCUIT



* Includes probe and jig capacitance
 ** All diodes FD600 or equivalent



$V_m = 1.5\text{ V}$ @ 25°C
 $= 1.2\text{ V}$ @ 125°C
 $= 1.7\text{ V}$ @ -55°C

	R_1	R_2	C_1
t_{pd+}	3.9 k Ω	2.0 k Ω	100 pF
t_{pd-}	390 Ω	2.0 k Ω	100 pF
20 MHz toggle	∞	∞	5.0 pF

MONOSTABLE MULTIVIBRATORS — 9941, 9951

The DT μ L 9941 and 9951 are monostable multivibrators designed for use with other members of the DT μ L family. They provide complementary output pulses which are typically 100 ns wide. This pulse width is adjustable by the addition of external components.

The TT μ L 9601 is a retriggerable one shot having several features which are superior to the 9941 and 9951. It is therefore recommended for new system designs in preference to the 9941 or 9951.

Fig. 1—LOGIC DIAGRAM AND PIN CONFIGURATION

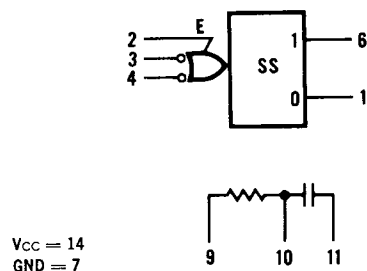
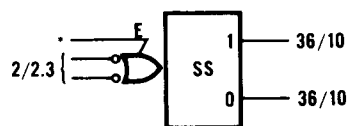
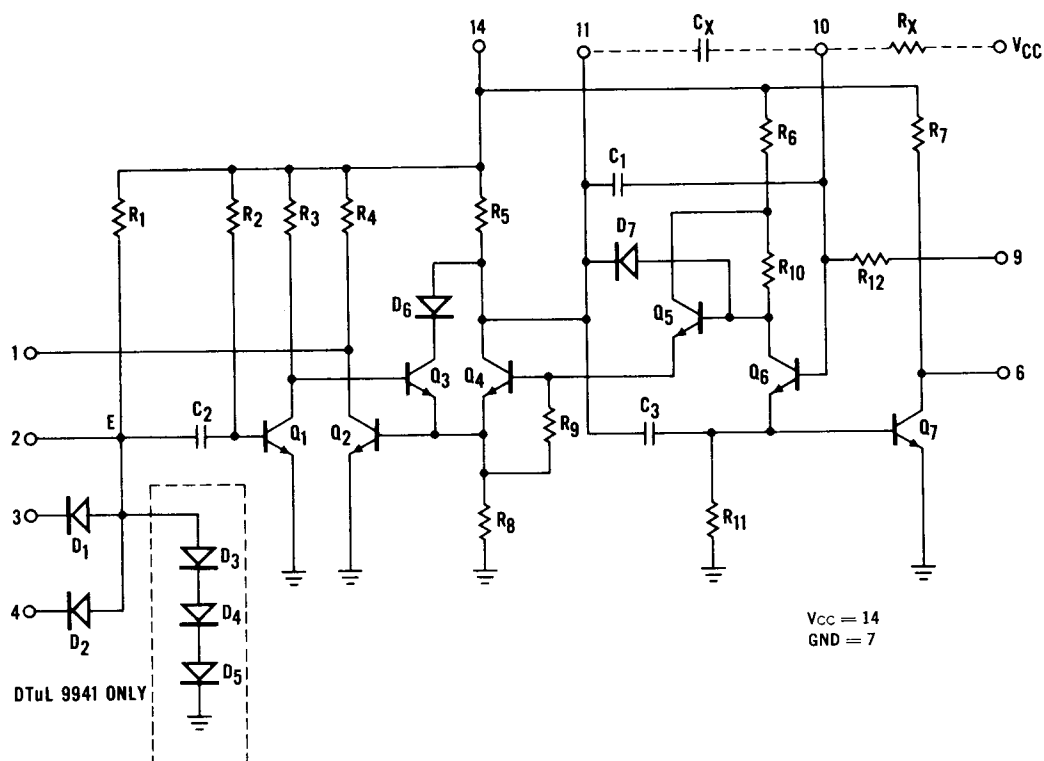


Fig. 2—LOADING FACTORS



1. Outputs can be wire "AND"ed
2. Extender pin allows increased number of inputs by addition of discrete diodes or extender element DT μ L9933.

Fig. 3—SCHEMATIC DIAGRAM



$R_1 = 2.1 \text{ k}\Omega$	$R_7 = 4.0 \text{ k}\Omega$	$C_1 = 20 \text{ pF}$
$R_2 = 7.0 \text{ k}\Omega$	$R_8 = 1.2 \text{ k}\Omega$	$C_2 = 25 \text{ pF}$
$R_3 = 2.4 \text{ k}\Omega$	$R_9 = 3.6 \text{ k}\Omega$	$C_3 = 15 \text{ pF}$
$R_4 = 4.0 \text{ k}\Omega$	$R_{11} = 24 \text{ k}\Omega$	
$R_5 = 2.0 \text{ k}\Omega$	$R_{12} = 9.0 \text{ k}\Omega$	
$R_6, R_{10} = 1.8 \text{ k}\Omega$		

FAIRCHILD DIODE-TRANSISTOR MICROLOGIC® INTEGRATED CIRCUITS

TABLE I
ELECTRICAL CHARACTERISTICS — 9941 AND 9951 ($T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$)

SYMBOL	CHARACTERISTIC	LIMITS						UNITS	CONDITIONS	
		-55°C		+25°C		+125°C				
		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.			
V _{OH}	Output High Voltage	2.5		2.5		2.5		Volts	V _{CC} = 4.5 V, I _{OH} = -0.18 mA	
V _{OL}	Output Low Voltage	0.4		0.4		0.4		Volts	V _{CC} = 5.5 V, I _{OL} = 15 mA V _{CC} = 4.5 V, I _{OL} = 15 mA	
I _{PDL}	Power Dissipation Current with Inputs Grounded			7.2 9.0				mA	V _{CC} = 5.0 V, Inputs = Gnd.	
I _F	Input Load Current	-2.93		-2.93		-2.75		mA	V _{CC} = 5.5 V, V _F = 0.4 V	
		-2.26		-2.26		-2.22		mA	V _{CC} = 4.5 V, V _F = 0.4 V	
I _R	Input Leakage Current	5.0		5.0		10.0		μA	V _{CC} = 5.5 V, V _R = 4.0 V, Pin 2 = Gnd.	
t _{pd+}	Turn Off Delay			40				ns	Pin 6	V _{CC} = 5.0 V See Figs. 4 & 5 on Page 23
t _{pd-}	Turn On Delay			40				ns	Pin 1	
PW	Pulse Width			90		330			Pin 1	
				70		330			Pin 6	
				90		220			Pin 1	
				70		160			Pin 6	

RULES FOR USE OF 9951

- With Pin 9 connected to V_{CC} and no external capacitor (C_X), the output pulse width is approximately 100 ns.
- With Pin 9 connected to V_{CC} and an external capacitor (C_X) connected between Pins 10 and 11, the output pulse width (T) is: $T \approx 4.5 (C_X + 20)$ with C_X in pF and T in ns.
- For improved pulse width control, Pin 9 is left open and a stable external resistor (R_X) of 9.0 k Ω minimum to 15 k Ω maximum is connected from Pin 10 to V_{CC} . The output pulse width is given by the expression: $T \approx 0.5 R_X (C_X + 20)$ with R_X in k Ω , C_X in pF and T in ns.
- The output duty cycle (pulse width/period) should not exceed 40%. It may be increased to 50% by adding a 2.0 k Ω resistor between Pin 11 and V_{CC} . Higher duty cycles are obtainable but the output pulse width and performance are less predictable.
- The maximum input fall time to trigger: 25 ns for a 1.0 volt swing; 50 ns for a 2.0 volt swing; 100 ns for a 4.0 volt swing.
- The minimum pulse width at output Pin 1 is approximately 100 ns. This pulse width may be decreased to 50 ns by connecting a 10 k Ω resistor between Pin 5 and V_{CC} . (not applicable to TO-100 package.)
- For pulse widths greater than 1.0 μs , Pin 1 should be used as the output and inverted if required.

SWITCHING TIME TEST CIRCUIT AND WAVEFORMS

Fig. 4

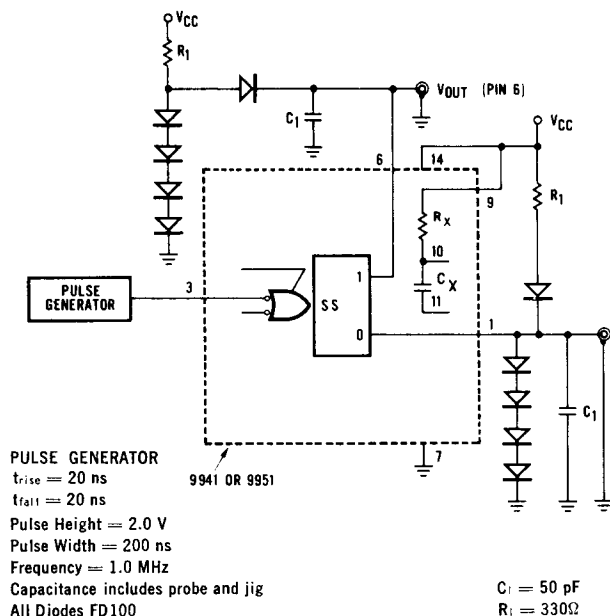
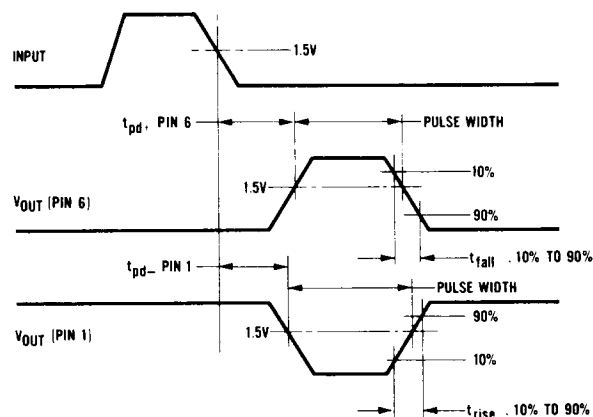


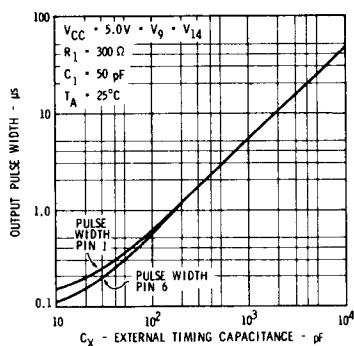
Fig. 5



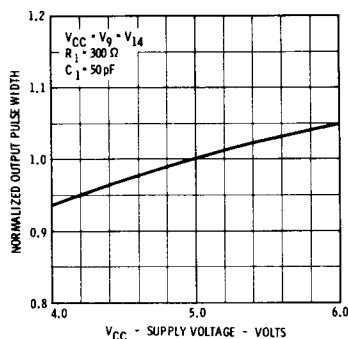
9941 AND 9951 TIMING CHARACTERISTICS

(Test circuit above is used with appropriate modifications where necessary)

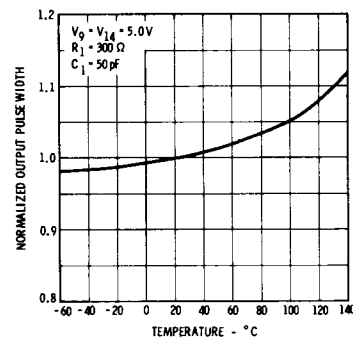
OUTPUT PULSE WIDTH VERSUS EXTERNAL TIMING CAPACITANCE C_X



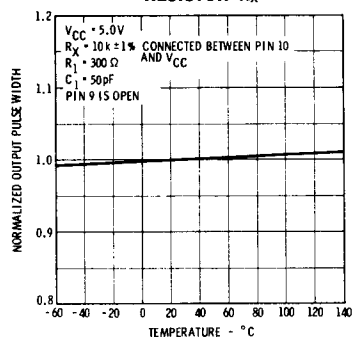
NORMALIZED OUTPUT PULSE WIDTH VERSUS SUPPLY VOLTAGE



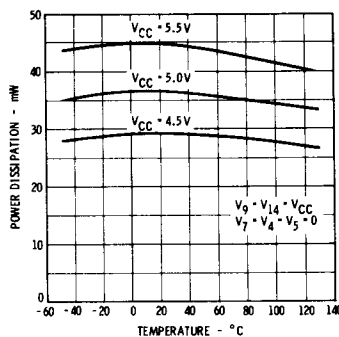
NORMALIZED OUTPUT PULSE WIDTH VERSUS TEMPERATURE



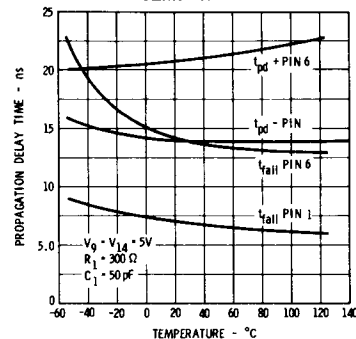
NORMALIZED OUTPUT PULSE WIDTH VERSUS TEMPERATURE USING EXTERNAL TIMING RESISTOR R_X



TYPICAL POWER DISSIPATION VERSUS TEMPERATURE

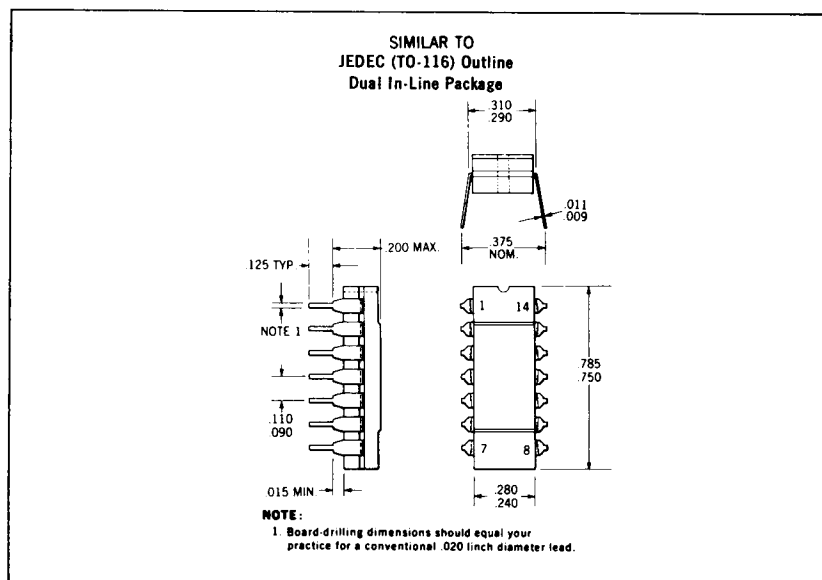


SWITCHING TIMES VERSUS TEMPERATURE

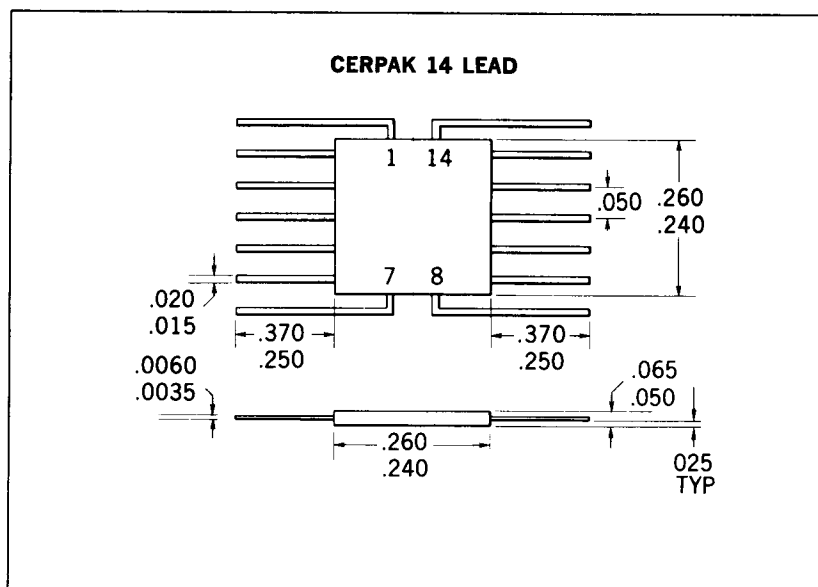


PACKAGE OUTLINES

U6A



U31



ORDER INFORMATION

To order diode-transistor micrologic elements specify U31XXXX51X for 14 pin Flat package; U6AXXX51X for 14 pin Dual In-Line package where XXXX is the four-digit number denoting the specific element desired and 51X is for -55°C to +125°C.